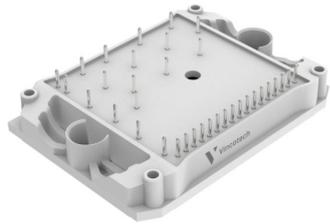
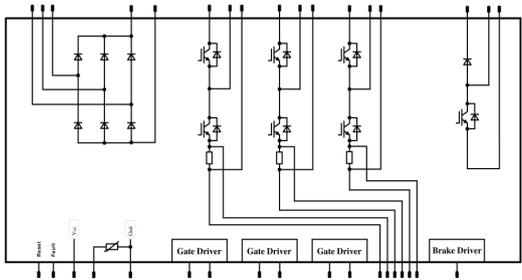




Vincotech

| <i>flow</i> IPM 1C   | 1200 V / 15 A  |
|--|--|
| <div style="border: 1px solid black; padding: 5px; margin-bottom: 5px;"> <p style="text-align: center; background-color: #cccccc; margin: 0;"><b>Features</b></p> <ul style="list-style-type: none"> <li>Three-phase input rectifier</li> <li>Three-phase inverter with emitter shunts</li> <li>Gate drives with bootstrap circuit</li> <li>Brake chopper with gate drive</li> <li>Overcurrent protection</li> <li>Undervoltage lockout</li> <li>Temperature sensor</li> </ul> </div> <div style="border: 1px solid black; padding: 5px; margin-bottom: 5px;"> <p style="text-align: center; background-color: #cccccc; margin: 0;"><b>Target applications</b></p> <ul style="list-style-type: none"> <li>Embedded Drives</li> <li>Industrial Drives</li> </ul> </div> <div style="border: 1px solid black; padding: 5px;"> <p style="text-align: center; background-color: #cccccc; margin: 0;"><b>Types</b></p> <ul style="list-style-type: none"> <li>20-1C12IBA015SH-LB18A08</li> </ul> </div> | <div style="border: 1px solid black; padding: 5px; margin-bottom: 5px;"> <p style="text-align: center; background-color: #cccccc; margin: 0;"><i>flow</i> 1C 12 mm housing</p>  </div> <div style="border: 1px solid black; padding: 5px;"> <p style="text-align: center; background-color: #cccccc; margin: 0;"><b>Schematic</b></p>  </div> |

## Maximum Ratings

$T_j = 25\text{ }^\circ\text{C}$ , unless otherwise specified

| Parameter                              | Symbol     | Condition   | Value | Unit                 |
|--|------------|---|-------|----------------------|
| <b>Rectifier Diode</b>                 |            |   |       |                      |
| Peak Repetitive Reverse Voltage        | $V_{RRM}$  |   | 1600  | V                    |
| Continuous (direct) forward current    | $I_F$      | $T_j = T_{jmax}$ $T_s = 80\text{ }^\circ\text{C}$                                     | 24    | A                    |
| Surge (non-repetitive) forward current | $I_{FSM}$  | 50 Hz Single Half Sine Wave<br>$t_p = 10\text{ ms}$ $T_j = 150\text{ }^\circ\text{C}$ | 230   | A                    |
| Surge current capability               | $I^2t$     |   | 260   | $\text{A}^2\text{s}$ |
| Total power dissipation                | $P_{tot}$  | $T_j = T_{jmax}$ $T_s = 80\text{ }^\circ\text{C}$                                     | 27    | W                    |
| Maximum Junction Temperature           | $T_{jmax}$ |   | 150   | $^\circ\text{C}$     |



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## Maximum Ratings

$T_j = 25\text{ °C}$ , unless otherwise specified

| Parameter                           | Symbol     | Condition                             | Value                 | Unit        |
|-------------------------------------|------------|---------------------------------------|-----------------------|-------------|
| <b>Inverter Switch</b>              |            |                                       |                       |             |
| Collector-emitter voltage           | $V_{CES}$  |                                       | 1200                  | V           |
| Collector current                   | $I_C$      | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 13                    | A           |
| Repetitive peak collector current   | $I_{CRM}$  | $t_p$ limited by $T_{jmax}$           | 45                    | A           |
| Total power dissipation             | $P_{tot}$  | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 29                    | W           |
| Short circuit ratings               | $t_{SC}$   | $T_j \leq 150\text{ °C}$              | 10                    | $\mu s$     |
|                                     | $V_{CC}$   | $V_{GE} = 15\text{ V}$                | 800                   | V           |
| Maximum junction temperature        | $T_{jmax}$ |                                       | 175                   | $^{\circ}C$ |
| <b>Inverter Diode</b>               |            |                                       |                       |             |
| Peak Repetitive Reverse Voltage     | $V_{RRM}$  |                                       | 1200                  | V           |
| Continuous (direct) forward current | $I_F$      | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 11                    | A           |
| Repetitive peak forward current     | $I_{FRM}$  |                                       | 30                    | A           |
| Total power dissipation             | $P_{tot}$  | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 16                    | W           |
| Maximum Junction Temperature        | $T_{jmax}$ |                                       | 150                   | $^{\circ}C$ |
| <b>Gate Driver Inverter</b>         |            |                                       |                       |             |
| Supply voltage                      | $V_{CC}$   |                                       | -0,5...+24            | V           |
| Logic input voltage                 | $V_{in}$   | UH, UL, VH, VL,<br>WH, WL, FO, RST    | -0,5... $V_{cc}$ +0,5 | V           |
| Internal current limit              | $I_{MAX}$  |                                       | 16,7                  | A           |
| <b>Inverter Shunt</b>               |            |                                       |                       |             |
| Max DC current                      | $I_{MAX}$  | $T_c = 25\text{ °C}$                  | 9                     | A           |
| <b>Brake Switch</b>                 |            |                                       |                       |             |
| Collector-emitter voltage           | $V_{CES}$  |                                       | 1200                  | V           |
| Collector current                   | $I_C$      | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 13                    | A           |
| Repetitive peak collector current   | $I_{CRM}$  | $t_p$ limited by $T_{jmax}$           | 45                    | A           |
| Total power dissipation             | $P_{tot}$  | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 29                    | W           |
| Short circuit ratings               | $t_{SC}$   | $T_j \leq 150\text{ °C}$              | 10                    | $\mu s$     |
|                                     | $V_{CC}$   | $V_{GE} = 15\text{ V}$                | 800                   | V           |
| Maximum junction temperature        | $T_{jmax}$ |                                       | 175                   | $^{\circ}C$ |



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## Maximum Ratings

$T_j = 25\text{ °C}$ , unless otherwise specified

| Parameter                           | Symbol     | Condition                             | Value | Unit |
|-------------------------------------|------------|---------------------------------------|-------|------|
| <b>Brake Diode</b>                  |            |                                       |       |      |
| Peak Repetitive Reverse Voltage     | $V_{RRM}$  |                                       | 1200  | V    |
| Continuous (direct) forward current | $I_F$      | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 6     | A    |
| Repetitive peak forward current     | $I_{FRM}$  |                                       | 15    | A    |
| Total power dissipation             | $P_{tot}$  | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 12    | W    |
| Maximum Junction Temperature        | $T_{jmax}$ |                                       | 150   | °C   |

### Brake Sw. Protection Diode

|                                     |            |                                       |      |    |
|-------------------------------------|------------|---------------------------------------|------|----|
| Peak Repetitive Reverse Voltage     | $V_{RRM}$  |                                       | 1200 | V  |
| Continuous (direct) forward current | $I_F$      | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 4    | A  |
| Repetitive peak forward current     | $I_{FRM}$  |                                       | 6    | A  |
| Total power dissipation             | $P_{tot}$  | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 8    | W  |
| Maximum Junction Temperature        | $T_{jmax}$ |                                       | 150  | °C |

### Gate Driver Brake

|                      |            |  |                           |    |
|----------------------|------------|--|---------------------------|----|
| Supply voltage       | $V_{CC}$   |  | 20                        | V  |
| Logic input voltage  | $V_{in}$   |  | $-0,3 \dots V_{cc} + 0,3$ | V  |
| Junction Temperature | $T_{jmax}$ |  | 150                       | °C |

## Module Properties

### Thermal Properties

|   |           |  |                             |    |
|---|-----------|--|-----------------------------|----|
| Storage temperature                             | $T_{stg}$ |  | $-40 \dots +125$            | °C |
| Operation temperature under switching condition | $T_{jop}$ |  | $-40 \dots (T_{jmax} - 25)$ | °C |

### Isolation Properties

|                            |            |                                     |           |    |
|----------------------------|------------|-------------------------------------|-----------|----|
| Isolation voltage          | $V_{isol}$ | DC Test Voltage* $t_p = 2\text{ s}$ | 6000      | V  |
|                            |            | AC Voltage $t_p = 1\text{ min}$     | 2500      | V  |
| Creepage distance          |            |                                     | min. 12,7 | mm |
| Clearance                  |            |                                     | 7,18      | mm |
| Comparative Tracking Index | CTI        |                                     | > 200     |    |

\*100 % tested in production



## Characteristic Values

| Parameter | Symbol | Conditions   |              |              |           |            | Value |     |     | Unit |
|-----------|--------|--------------|--------------|--------------|-----------|------------|-------|-----|-----|------|
|           |        | $V_{GS}$ [V] | $V_{GE}$ [V] | $V_{DS}$ [V] | $I_C$ [A] | $T_j$ [°C] | Min   | Typ | Max |      |

### Rectifier Diode

#### Static

|                         |       |  |  |      |    |           |  |              |            |         |
|-------------------------|-------|--|--|------|----|-----------|--|--------------|------------|---------|
| Forward voltage         | $V_F$ |  |  |      | 30 | 25<br>125 |  | 1,25<br>1,24 | 1,29       | V       |
| Reverse leakage current | $I_r$ |  |  | 1600 |    | 25<br>150 |  |              | 10<br>1000 | $\mu$ A |

#### Thermal

|                                     |               |   |  |  |  |  |  |      |  |     |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | phase-change material<br>$\lambda = 3,4$ W/mK |  |  |  |  |  | 2,60 |  | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|

### Inverter Switch

#### Static

|                                      |               |                   |    |      |        |           |      |              |      |          |
|--------------------------------------|---------------|-------------------|----|------|--------|-----------|------|--------------|------|----------|
| Gate-emitter threshold voltage       | $V_{GE(th)}$  | $V_{GE} = V_{CE}$ |    |      | 0,0005 | 25        | 5,3  | 5,8          | 6,3  | V        |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ |                   | 15 |      | 15     | 25<br>150 | 1,78 | 1,89<br>2,28 | 2,42 | V        |
| Collector-emitter cut-off current    | $I_{CES}$     |                   | 0  | 1200 |        | 25        |      |              | 2    | $\mu$ A  |
| Internal gate resistance             | $r_g$         |                   |    |      |        |           |      | none         |      | $\Omega$ |
| Input capacitance                    | $C_{ies}$     | $f = 1$ MHz       | 0  | 25   | 25     |           |      | 875          |      | pF       |
| Output capacitance                   | $C_{oes}$     |                   |    |      |        |           |      | 75           |      |          |
| Reverse transfer capacitance         | $C_{res}$     |                   |    |      |        |           |      | 45           |      |          |

#### Thermal

|                                     |               |   |  |  |  |  |  |      |  |     |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | phase-change material<br>$\lambda = 3,4$ W/mK |  |  |  |  |  | 3,26 |  | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|

#### Dynamic

|                             |              |  |                                   |     |   |     |  |       |  |     |
|-----------------------------|--------------|--|-----------------------------------|-----|---|-----|--|-------|--|-----|
| Turn-on delay time*         | $t_{d(on)}$  | $Q_{iFWD} = 1,3$ $\mu$ C<br>$Q_{tFWD} = 2,5$ $\mu$ C | $V_{CC} = 15$ V<br>$V_{IN} = 5$ V | 600 | 9 | 25  |  | 1507  |  | ns  |
| Rise time                   | $t_r$        |  |                                   |     |   | 125 |  | 17    |  |     |
|                             |              |  |                                   |     |   | 125 |  | 19    |  |     |
| Turn-off delay time*        | $t_{d(off)}$ |  |                                   |     |   | 25  |  | 1507  |  |     |
|                             |              |  |                                   |     |   | 125 |  | 2012  |  |     |
| Fall time                   | $t_f$        |  |                                   |     |   | 25  |  | 25    |  |     |
|                             |              | 125  |                                   | 88  |   |     |  |       |  |     |
| Turn-on energy (per pulse)  | $E_{on}$     |  |                                   |     |   | 25  |  | 0,559 |  | mWs |
| Turn-off energy (per pulse) | $E_{off}$    |  |                                   |     |   | 125 |  | 0,816 |  |     |
|                             |              |  |                                   |     |   | 25  |  | 0,395 |  |     |
|                             |              |  |                                   |     |   | 125 |  | 0,730 |  |     |

\* times include gate driver propagation delay



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## Characteristic Values

| Parameter | Symbol | Conditions   |              |           |            |     | Value |     |  | Unit |
|-----------|--------|--------------|--------------|-----------|------------|-----|-------|-----|--|------|
|           |        | $V_{GE}$ [V] | $V_{CE}$ [V] | $I_C$ [A] | $T_j$ [°C] | Min | Typ   | Max |  |      |

### Inverter Diode

#### Static

| Parameter               | Symbol | $V_{GE}$ [V] | $V_{CE}$ [V] | $I_C$ [A] | $T_j$ [°C] | Min | Typ          | Max | Unit |
|-------------------------|--------|--------------|--------------|-----------|------------|-----|--------------|-----|------|
| Forward voltage         | $V_F$  |              |              | 15        | 25<br>125  |     | 1,76<br>1,73 |     | V    |
| Reverse leakage current | $I_r$  |              | 1200         |           | 25         |     |              | 250 | μA   |

#### Thermal

| Parameter                           | Symbol        | Conditions                                    | Value | Unit |
|-------------------------------------|---------------|---|-------|------|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | phase-change material<br>$\lambda = 3,4$ W/mK | 4,37  | K/W  |

#### Dynamic

| Parameter                             | Symbol               | $di/dt$                                  | $V_{CC}$                          | $V_{IN}$ | $I_C$ | $T_j$ | Min | Typ   | Max | Unit |
|---------------------------------------|----------------------|--|-----------------------------------|----------|-------|-------|-----|-------|-----|------|
| Peak recovery current                 | $I_{RRM}$            | $di/dt = 595$ A/μs<br>$di/dt = 536$ A/μs | $V_{CC} = 15$ V<br>$V_{IN} = 5$ V | 600      | 9     | 25    |     | 9     |     | A    |
| Reverse recovery time                 | $t_{rr}$             |  |                                   |          |       | 125   |     | 12    |     | ns   |
| Recovered charge                      | $Q_r$                |  |                                   |          |       | 25    |     | 1,272 |     | μC   |
| Reverse recovered energy              | $E_{rec}$            |  |                                   |          |       | 125   |     | 2,489 |     | mWs  |
| Peak rate of fall of recovery current | $(di_{rf}/dt)_{max}$ |  |                                   |          |       | 25    |     | 38    |     | A/μs |
|                                       |                      | 125                                      |                                   | 40       |       |       |     |       |     |      |



## Characteristic Values

| Parameter | Symbol | Conditions   |              |           |            |     | Value |     |  | Unit |
|-----------|--------|--------------|--------------|-----------|------------|-----|-------|-----|--|------|
|           |        | $V_{GE}$ [V] | $V_{CE}$ [V] | $I_C$ [A] | $T_j$ [°C] | Min | Typ   | Max |  |      |

### Gate Driver\*

#### Static

|  |                    |   |     |     |     |      |      |      |    |
|--|--------------------|---|-----|-----|-----|------|------|------|----|
| Recommended supply voltage               | $V_{CC}$           |   |     |     |     | 13,5 | 15   | 20   | V  |
| Power on reset trip voltage              | $V_{POR}$          |   |     |     |     | 4,0  | 5,5  | 7,5  | V  |
| Internal current limit                   | $I_{MAX}$          |   |     |     |     | 13,3 | 16,7 | 20   | A  |
| Quiescent supply current                 | $I_q$              |   |     |     |     |      | 3    | 4,5  | mA |
| Logic "1" input voltage                  | $V_{IH}$           | UH, UL, VH,<br>VL, WH, WL, RST                  |     |     |     | 2,2  | 3    | 4    | V  |
| Logic "0" input voltage                  | $V_{IL}$           |   | 0,6 | 1,5 | 2,1 | V    |      |      |    |
| Logic "1" input current                  | $I_{inH}$          | $V_{in} = 5 V$                                  |     |     |     | 0,6  | 1    | 1,4  | mA |
| Logic "0" input current                  | $I_{inL}$          | $V_{in} = 0 V$                                  |     |     |     | 0    | 0    | 0,01 | mA |
| Input signal filter time                 | $t_{Filt}$         | UH, UL, VH, VL, WH,<br>WL, FO (in), RST (pulse) |     |     |     | 80   | 200  | 500  | ns |
| Logic "1" FAULT output**                 | $V_{outFAULTH}$    |   |     |     |     |      |      | 0,95 | V  |
| Logic "1" FAULT input treshold voltage** | $V_{inFAULTH}$     |   |     |     |     | 0,6  | 1,5  | 2,1  | V  |
| Logic "0" FAULT input treshold voltage** | $V_{inFAULTL}$     |   |     |     |     | 2,2  | 3    | 4    | V  |
| Under voltage reset voltage              | $V_{UVreset}$      |   |     |     |     | 10   | 10,8 | 11,6 | V  |
| Under voltage trip voltage               | $V_{UVtrip}$       |   |     |     |     | 10,5 | 11,3 | 12,1 | V  |
| Under voltage hysteresis voltage         | $V_{UVhysteresis}$ |   |     |     |     | 0,2  | 0,5  | 0,8  | V  |

\* For more information see Mitsubishi's M81738FP datasheet. The recommended minimum input pulse width is 2.47  $\mu s$ .

\*\* FAULT active low with pull up resistor to Vcc.

### Inverter Shunt

#### Static

|            |     |  |  |  |  |  |    |  |            |
|------------|-----|--|--|--|--|--|----|--|------------|
| Resistance | $R$ |  |  |  |  |  | 30 |  | m $\Omega$ |
|------------|-----|--|--|--|--|--|----|--|------------|



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## Characteristic Values

| Parameter | Symbol | Conditions   |              |              |           |            | Value |     |     | Unit |
|-----------|--------|--------------|--------------|--------------|-----------|------------|-------|-----|-----|------|
|           |        | $V_{GS}$ [V] | $V_{GE}$ [V] | $V_{DS}$ [V] | $I_D$ [A] | $T_j$ [°C] | Min   | Typ | Max |      |

### Brake Switch

#### Static

| Parameter                            | Symbol       | Conditions        | $V_{GS}$ [V] | $V_{GE}$ [V] | $V_{DS}$ [V] | $I_D$ [A] | $T_j$ [°C] | Min  | Typ          | Max  | Unit |
|--------------------------------------|--------------|-------------------|--------------|--------------|--------------|-----------|------------|------|--------------|------|------|
| Gate-emitter threshold voltage       | $V_{GE(th)}$ | $V_{GE} = V_{CE}$ |              |              |              | 0,0005    | 25         | 5,3  | 5,8          | 6,3  | V    |
| Collector-emitter saturation voltage | $V_{CEsat}$  |                   | 15           |              |              | 15        | 25<br>150  | 1,78 | 1,89<br>2,28 | 2,42 | V    |
| Collector-emitter cut-off current    | $I_{CES}$    |                   | 0            | 1200         |              |           | 25         |      |              | 2    | μA   |
| Internal gate resistance             | $r_g$        |                   |              |              |              |           |            |      | none         |      | Ω    |
| Input capacitance                    | $C_{ies}$    |                   |              |              |              |           |            |      | 875          |      | pF   |
| Output capacitance                   | $C_{oes}$    | $f = 1$ MHz       | 0            | 25           |              | 25        |            |      | 75           |      |      |
| Reverse transfer capacitance         | $C_{res}$    |                   |              |              |              |           |            |      | 45           |      |      |

#### Thermal

| Parameter                           | Symbol        | Conditions                                    | $V_{GS}$ [V] | $V_{GE}$ [V] | $V_{DS}$ [V] | $I_D$ [A] | $T_j$ [°C] | Min | Typ  | Max | Unit |
|-------------------------------------|---------------|---|--------------|--------------|--------------|-----------|------------|-----|------|-----|------|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | phase-change material<br>$\lambda = 3,4$ W/mK |              |              |              |           |            |     | 3,26 |     | K/W  |

#### Dynamic

| Parameter                   | Symbol       | Conditions                        | $V_{GS}$ [V] | $V_{GE}$ [V] | $V_{DS}$ [V] | $I_D$ [A] | $T_j$ [°C] | Min   | Typ | Max | Unit |
|-----------------------------|--------------|-----------------------------------|--------------|--------------|--------------|-----------|------------|-------|-----|-----|------|
| Turn-on delay time*         | $t_{d(on)}$  | $V_{IN} = 5$ V<br>$V_{CC} = 15$ V | 600          | 10           |              |           |            | 25    | 44  |     | ns   |
| Rise time                   | $t_r$        |                                   |              |              |              |           |            | 125   | 49  |     |      |
| Turn-off delay time*        | $t_{d(off)}$ |                                   |              |              |              |           |            | 25    | 17  |     |      |
| Fall time                   | $t_f$        |                                   |              |              |              |           |            | 125   | 20  |     |      |
| Turn-on energy (per pulse)  | $E_{on}$     |                                   |              |              |              |           |            | 25    | 299 |     |      |
| Turn-off energy (per pulse) | $E_{off}$    |                                   |              |              |              |           |            | 125   | 369 |     |      |
|                             |              | 25                                | 16           |              |              |           |            | 0,579 |     | mWs |      |
|                             |              | 125                               | 43           |              |              |           |            | 0,771 |     |     |      |
|                             |              | 25                                |              |              |              |           |            | 0,339 |     |     |      |
|                             |              | 125                               |              |              |              |           |            | 0,598 |     |     |      |

\* times include gate driver deadtime



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### Characteristic Values

| Parameter | Symbol | Conditions                   |   |                                     |            |     | Value |     |  | Unit |
|-----------|--------|------------------------------|---|-------------------------------------|------------|-----|-------|-----|--|------|
|           |        | $V_{GE}$ [V]<br>$V_{GS}$ [V] | $V_{CE}$ [V]<br>$V_{DS}$ [V]<br>$V_F$ [V] | $I_C$ [A]<br>$I_D$ [A]<br>$I_F$ [A] | $T_j$ [°C] | Min | Typ   | Max |  |      |

#### Brake Diode

##### Static

|                         |       |  |  |      |     |                  |  |                      |     |         |
|-------------------------|-------|--|--|------|-----|------------------|--|----------------------|-----|---------|
| Forward voltage         | $V_F$ |  |  |      | 7,5 | 25<br>125<br>150 |  | 2,00<br>1,99<br>1,99 |     | V       |
| Reverse leakage current | $I_r$ |  |  | 1200 |     | 25               |  |                      | 250 | $\mu$ A |

##### Thermal

|                                     |               |   |  |  |  |  |  |      |  |     |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | phase-change material<br>$\lambda = 3,4$ W/mK |  |  |  |  |  | 5,86 |  | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|

##### Dynamic

|                                       |                      |  |                                   |     |    |     |  |       |  |            |
|---------------------------------------|----------------------|--|-----------------------------------|-----|----|-----|--|-------|--|------------|
| Peak recovery current                 | $I_{RRM}$            | $di/dt = 588$ A/ $\mu$ s<br>$di/dt = 560$ A/ $\mu$ s | $V_{IN} = 5$ V<br>$V_{CC} = 15$ V | 600 | 10 | 25  |  | 8     |  | A          |
| Reverse recovery time                 | $t_{rr}$             |  |                                   |     |    | 125 |  | 9     |  | ns         |
| Recovered charge                      | $Q_r$                |  |                                   |     |    | 25  |  | 1,008 |  | $\mu$ C    |
| Reverse recovered energy              | $E_{rec}$            |  |                                   |     |    | 125 |  | 1,759 |  | mWs        |
| Peak rate of fall of recovery current | $(di_{rf}/dt)_{max}$ |  |                                   |     |    | 25  |  | 31    |  | A/ $\mu$ s |
|                                       |                      |  |                                   |     |    | 125 |  | 40    |  |            |

#### Brake Sw. Protection Diode

##### Static

|                         |       |  |  |      |   |           |  |              |     |         |
|-------------------------|-------|--|--|------|---|-----------|--|--------------|-----|---------|
| Forward voltage         | $V_F$ |  |  |      | 3 | 25<br>150 |  | 1,65<br>1,51 | 2,3 | V       |
| Reverse leakage current | $I_r$ |  |  | 1200 |   | 25        |  |              | 250 | $\mu$ A |

##### Thermal

|                                     |               |   |  |  |  |  |  |      |  |     |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | phase-change material<br>$\lambda = 3,4$ W/mK |  |  |  |  |  | 9,21 |  | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|



## Characteristic Values

| Parameter | Symbol | Conditions                   |   |                                     |            |     | Value |     |  | Unit |
|-----------|--------|------------------------------|---|-------------------------------------|------------|-----|-------|-----|--|------|
|           |        | $V_{GE}$ [V]<br>$V_{GS}$ [V] | $V_{CE}$ [V]<br>$V_{DS}$ [V]<br>$V_F$ [V] | $I_C$ [A]<br>$I_D$ [A]<br>$I_F$ [A] | $T_j$ [°C] | Min | Typ   | Max |  |      |

### Gate Driver Brake

#### Static

|                                   |           |                |  |  |  |      |     |     |            |
|-----------------------------------|-----------|----------------|--|--|--|------|-----|-----|------------|
| Recommended supply voltage        | $V_{CC}$  |                |  |  |  | 4,5  | 15  | 18  | V          |
| Turn-On Voltage                   | $V_{ON}$  |                |  |  |  | 3,5  | 3,9 | 4,3 | V          |
| Turn-Off Voltage                  | $V_{OFF}$ |                |  |  |  | 3,3  | 3,7 | 4,1 | V          |
| Logic "1" input threshold voltage | $V_{inH}$ |                |  |  |  | 30   |     |     | % $V_{DD}$ |
| Logic "0" input threshold voltage | $V_{inL}$ |                |  |  |  |      |     | 70  | % $V_{DD}$ |
| Logic "1" input current           | $I_{inH}$ | $V_{in} = 5$ V |  |  |  | -1   |     | 175 | $\mu$ A    |
| Logic "0" input current           | $I_{inL}$ | $V_{in} = 0$ V |  |  |  | -175 |     | 1   | $\mu$ A    |
| Logic Hysteresis Voltage          | $V_{HYS}$ |                |  |  |  |      | 17  |     | % $V_{DD}$ |

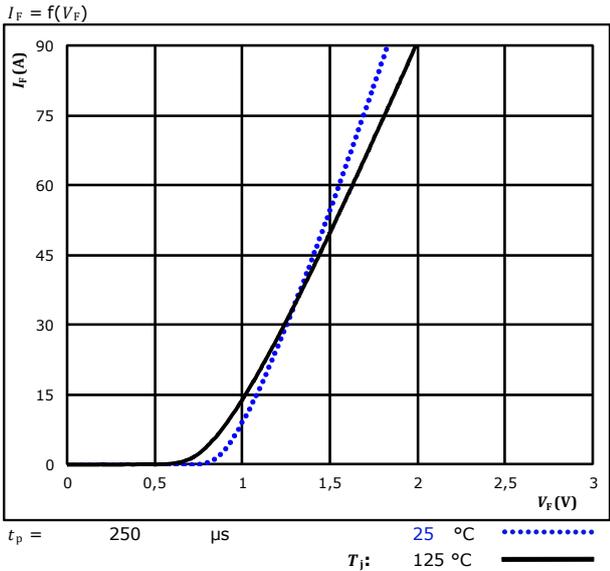
### Thermistor

|                            |                |                         |  |  |  |     |     |      |     |            |
|----------------------------|----------------|-------------------------|--|--|--|-----|-----|------|-----|------------|
| Rated resistance           | $R$            |                         |  |  |  | 25  |     | 22   |     | k $\Omega$ |
| Deviation of $R_{100}$     | $\Delta_{R/R}$ | $R_{100} = 1486 \Omega$ |  |  |  | 100 | -12 |      | +14 | %          |
| Power dissipation          | $P$            |                         |  |  |  | 25  |     | 200  |     | mW         |
| Power dissipation constant |                |                         |  |  |  | 25  |     | 2    |     | mW/K       |
| B-value                    | $B_{(25/50)}$  | Tol. $\pm 3\%$          |  |  |  | 25  |     | 3950 |     | K          |
| B-value                    | $B_{(25/100)}$ | Tol. $\pm 3\%$          |  |  |  | 25  |     | 3998 |     | K          |
| Vincotech NTC Reference    |                |                         |  |  |  |     |     |      | B   |            |

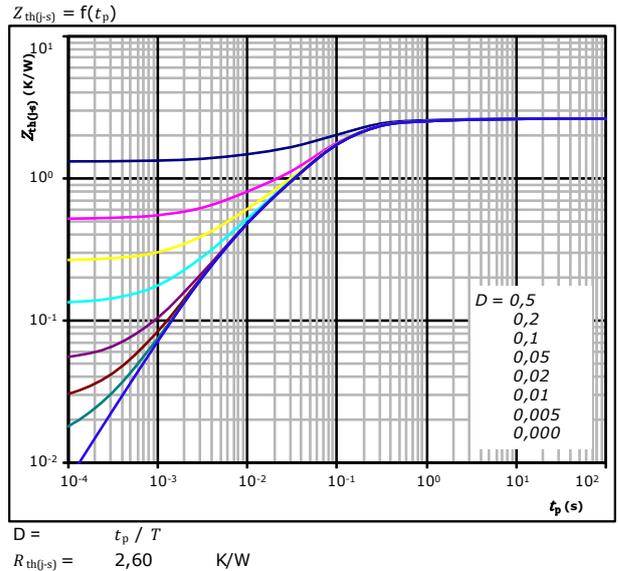


### Rectifier Diode Characteristics

**figure 1. Rectifier Diode**  
Typical forward characteristics



**figure 2. Rectifier Diode**  
Transient thermal impedance as a function of pulse width



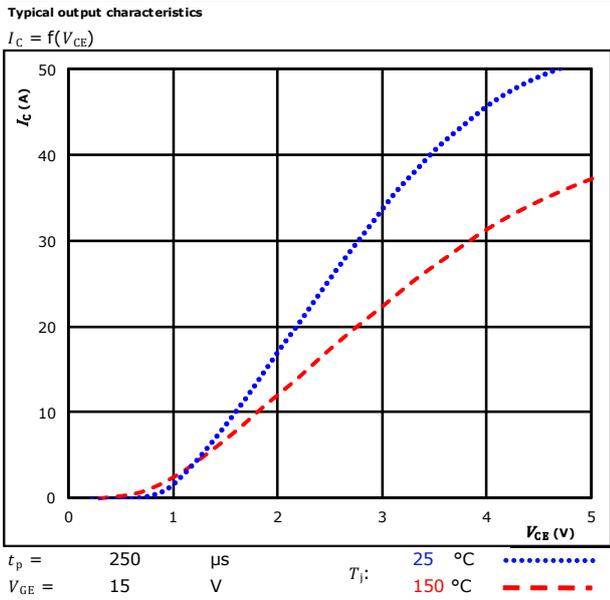
Diode thermal model values

| $R$ (K/W) | $\tau$ (s) |
|-----------|------------|
| 6,39E-02  | 7,39E+00   |
| 1,82E-01  | 8,47E-01   |
| 1,37E+00  | 1,17E-01   |
| 7,19E-01  | 4,63E-02   |
| 2,48E-01  | 5,84E-03   |
| 2,07E-02  | 5,09E-03   |

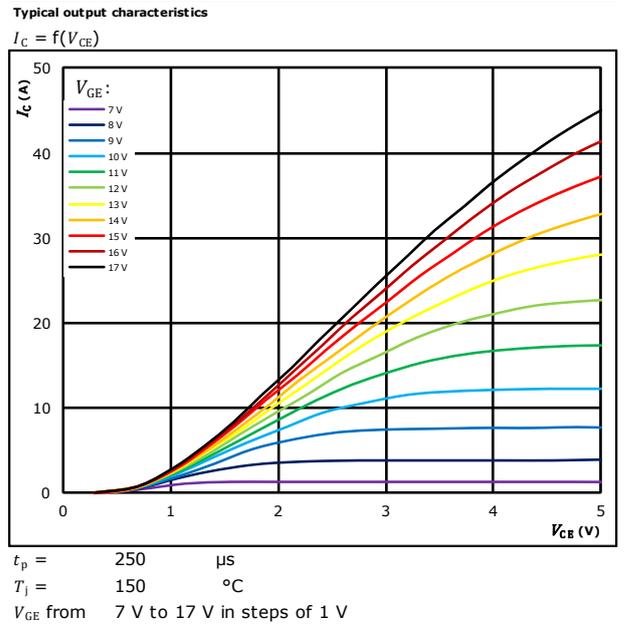


## Inverter Switch Characteristics

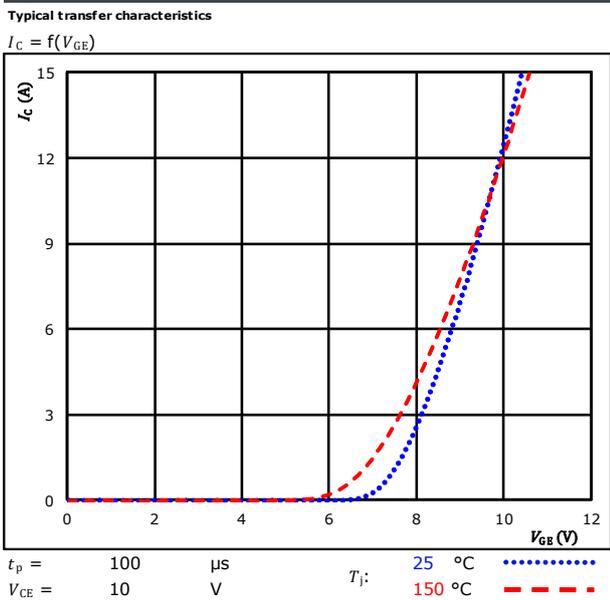
**figure 1.** IGBT



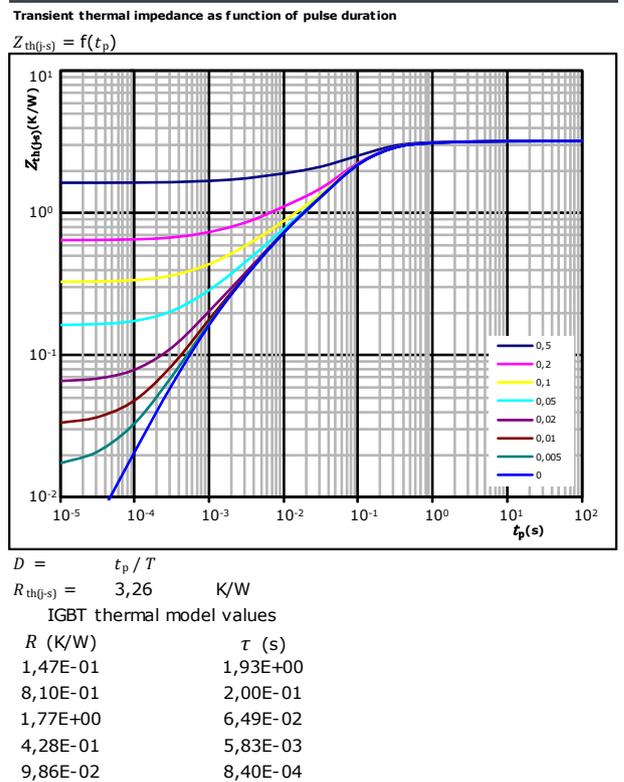
**figure 2.** IGBT



**figure 3.** IGBT



**figure 4.** IGBT



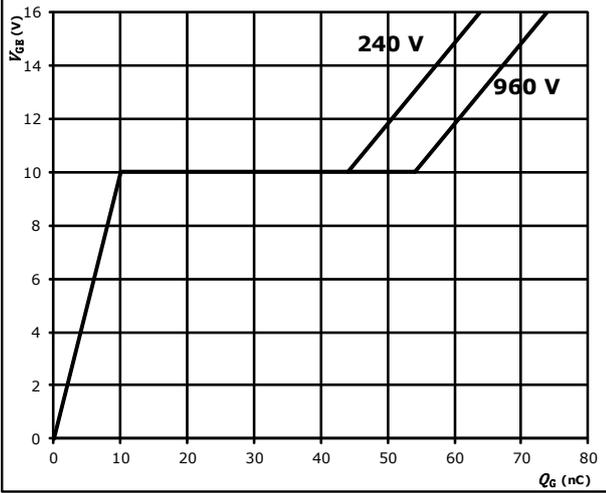


### Inverter Switch Characteristics

**figure 5.** IGBT

Gate voltage vs gate charge

$V_{GE} = f(Q_G)$

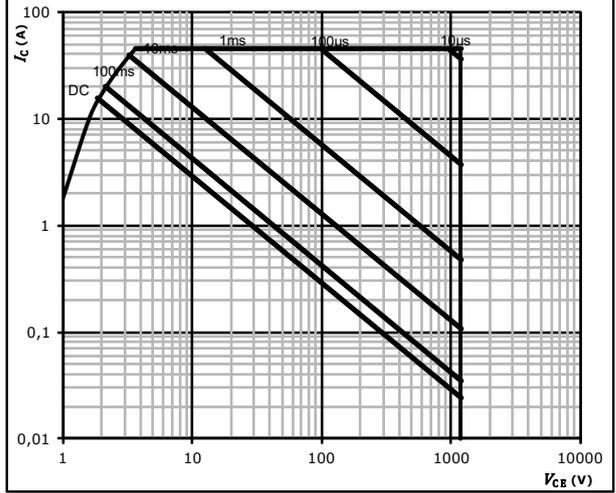


$I_C = 15$  A

**figure 6.** IGBT

Safe operating area

$I_C = f(V_{CE})$

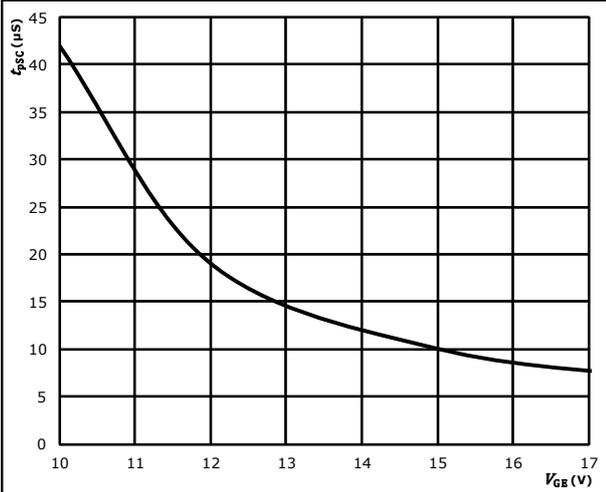


$D =$  single pulse  
 $T_s = 80$  °C  
 $V_{GE} = \pm 15$  V  
 $T_j = T_{jmax}$

**figure 7.** IGBT

Short circuit duration as a function of  $V_{GE}$

$t_{pSC} = f(V_{GE})$

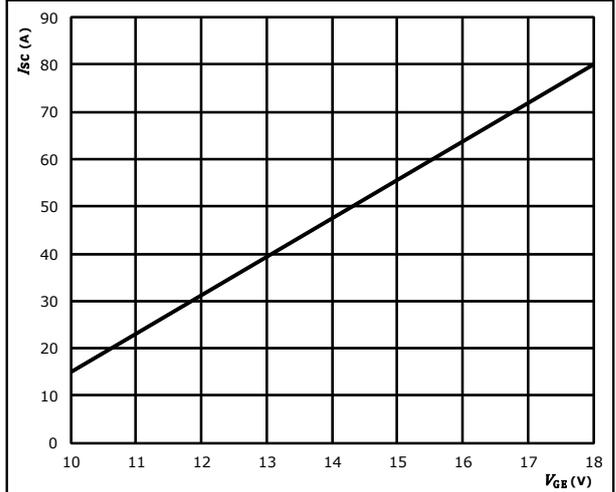


$V_{CE} \leq 600$  V  
 $T_j \leq 150$  °C

**figure 8.** IGBT

Typical short circuit current as a function of  $V_{GE}$

$I_{SC} = f(V_{GE})$



$V_{CE} \leq 600$  V  
 $T_j = 25$  °C



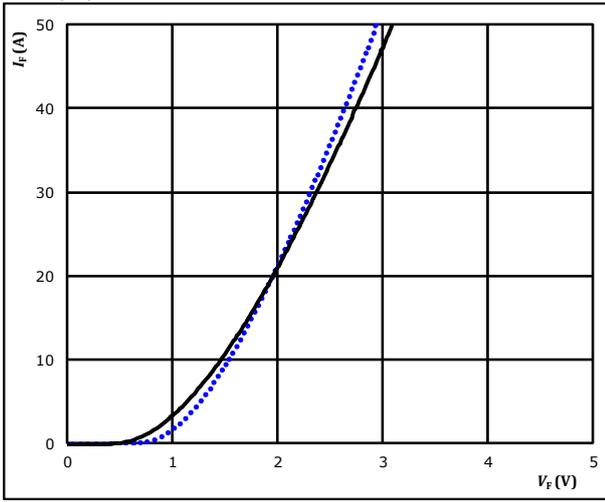
Vincotech

### Inverter Diode Characteristics

figure 1. FWD

Typical forward characteristics

$$I_F = f(V_F)$$

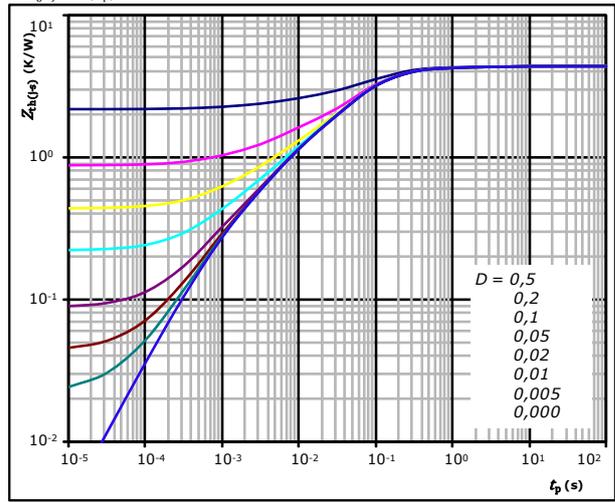


$t_p = 250 \mu s$   $T_j: 25 \text{ }^\circ\text{C}$  (dotted blue line)  
 $125 \text{ }^\circ\text{C}$  (solid black line)

figure 2. FWD

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T$   
 $R_{th(j-s)} = 4,37 \text{ K/W}$

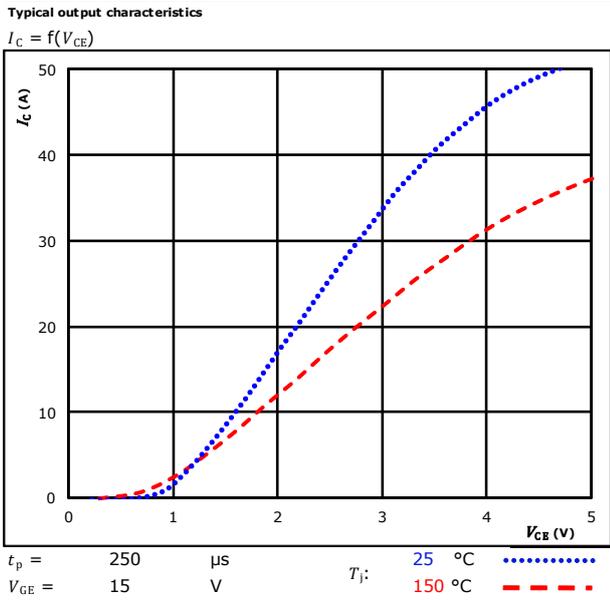
FWD thermal model values

| $R$ (K/W) | $\tau$ (s) |
|-----------|------------|
| 1,74E-01  | 2,44E+00   |
| 8,11E-01  | 2,19E-01   |
| 2,50E+00  | 6,24E-02   |
| 7,01E-01  | 6,51E-03   |
| 1,90E-01  | 8,68E-04   |

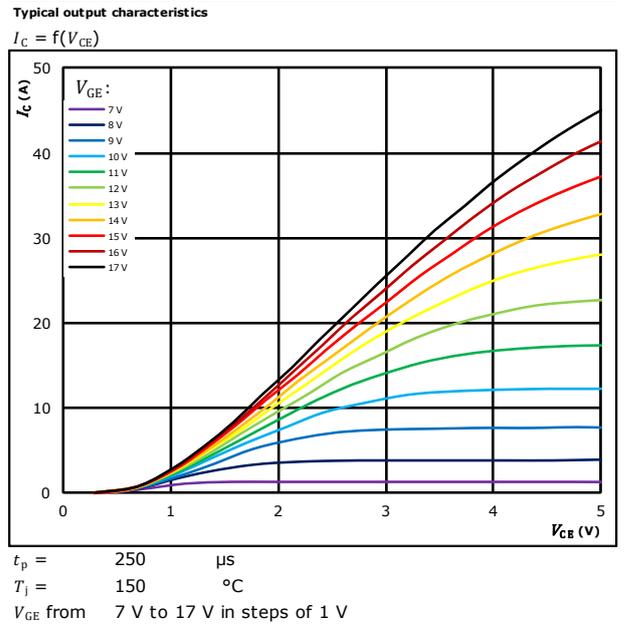


### Brake Switch Characteristics

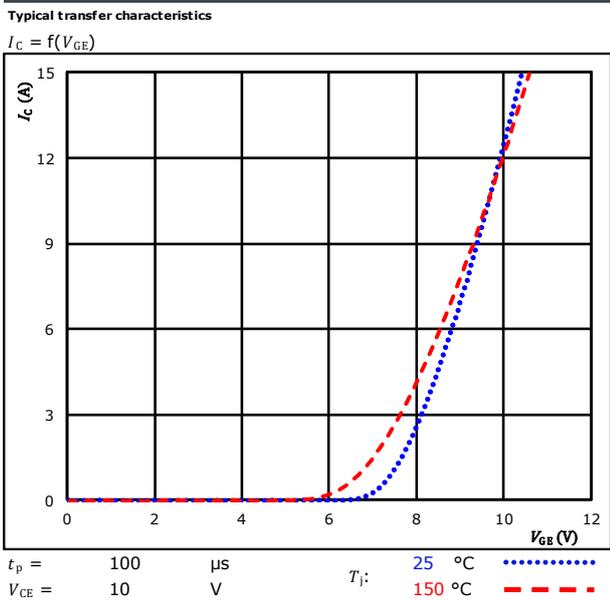
**figure 1.** IGBT



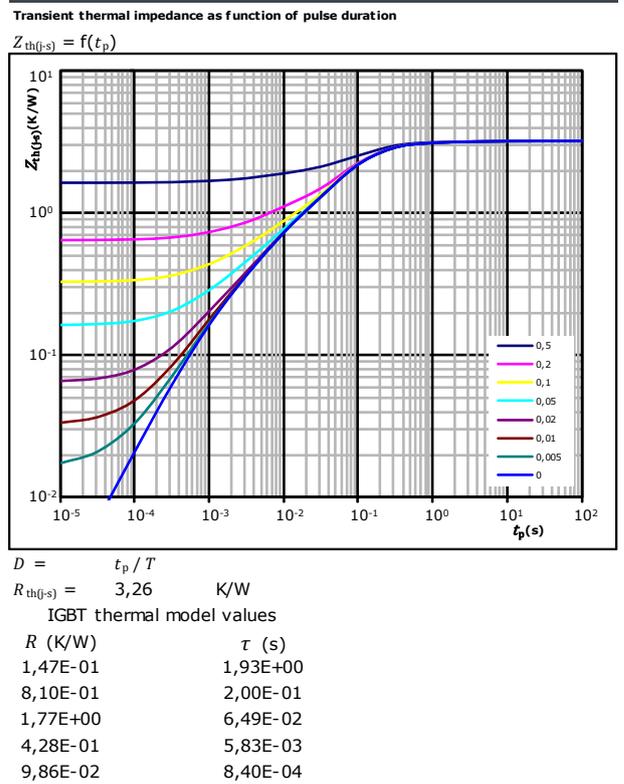
**figure 2.** IGBT



**figure 3.** IGBT



**figure 4.** IGBT

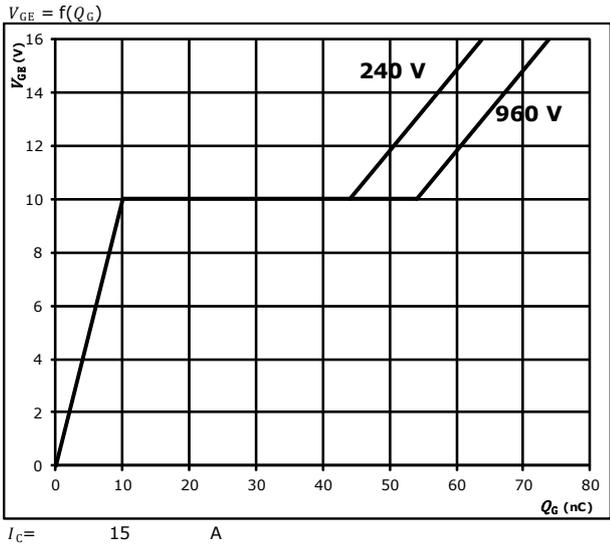




### Brake Switch Characteristics

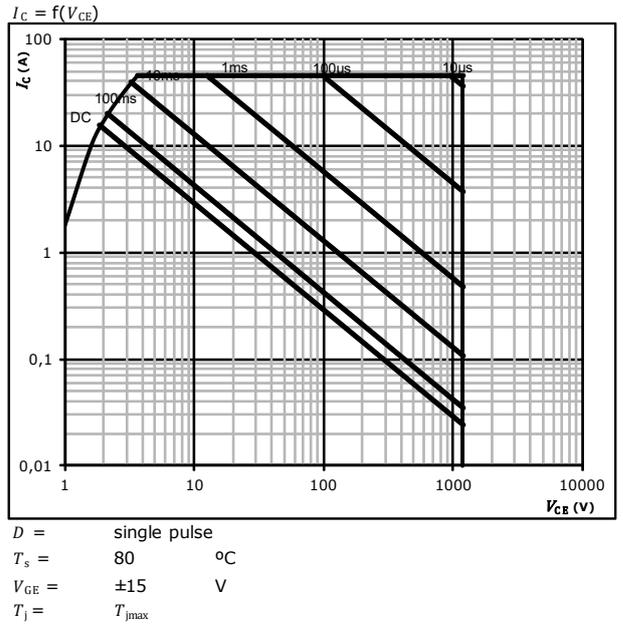
**figure 5.** IGBT

Gate voltage vs gate charge



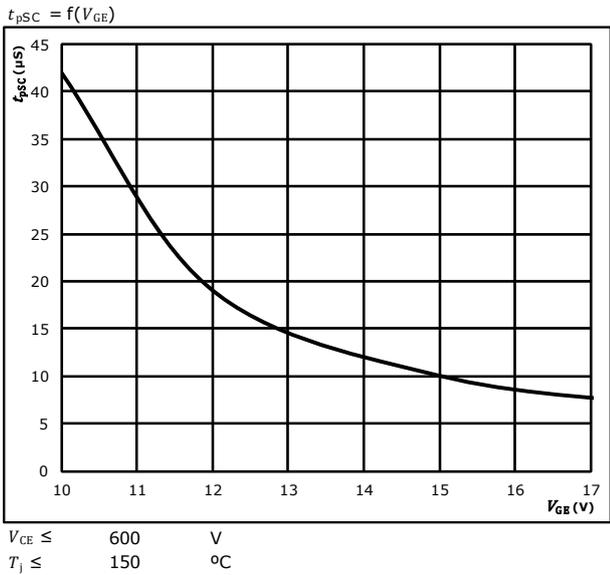
**figure 6.** IGBT

Safe operating area



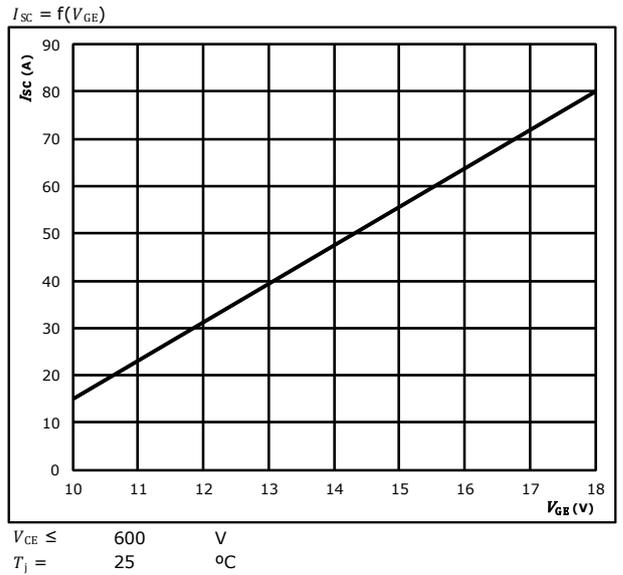
**figure 7.** IGBT

Short circuit duration as a function of  $V_{GE}$



**figure 8.** IGBT

Typical short circuit current as a function of  $V_{GE}$



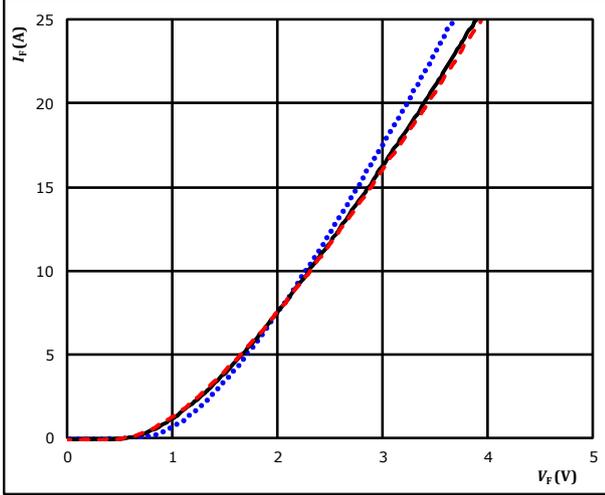


### Brake Diode Characteristics

**figure 1.** FWD

**Typical forward characteristics**

$$I_F = f(V_F)$$



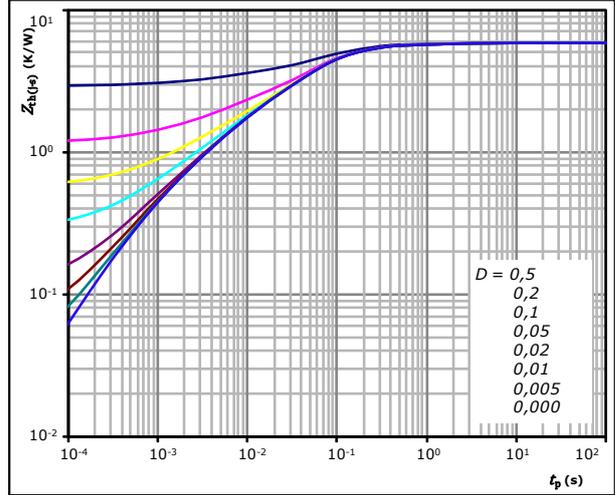
$t_p = 250 \mu s$

$T_j:$  25 °C (blue dotted line)  
125 °C (black solid line)  
150 °C (red dashed line)

**figure 2.** FWD

**Transient thermal impedance as a function of pulse width**

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T$

$R_{th(j-s)} = 5,86 \text{ K/W}$

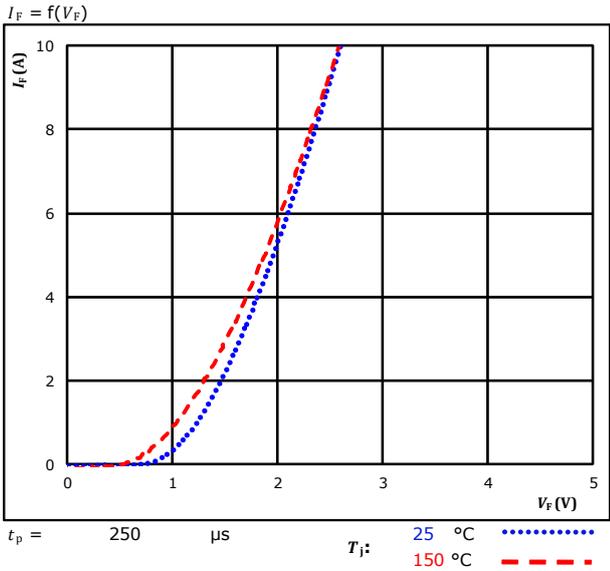
FWD thermal model values

| $R \text{ (K/W)}$ | $\tau \text{ (s)}$ |
|-------------------|--------------------|
| 8,94E-02          | 4,38E+00           |
| 3,15E-01          | 8,32E-01           |
| 2,01E+00          | 1,12E-01           |
| 2,33E+00          | 3,80E-02           |
| 9,08E-01          | 4,25E-03           |
| 2,13E-01          | 5,94E-04           |

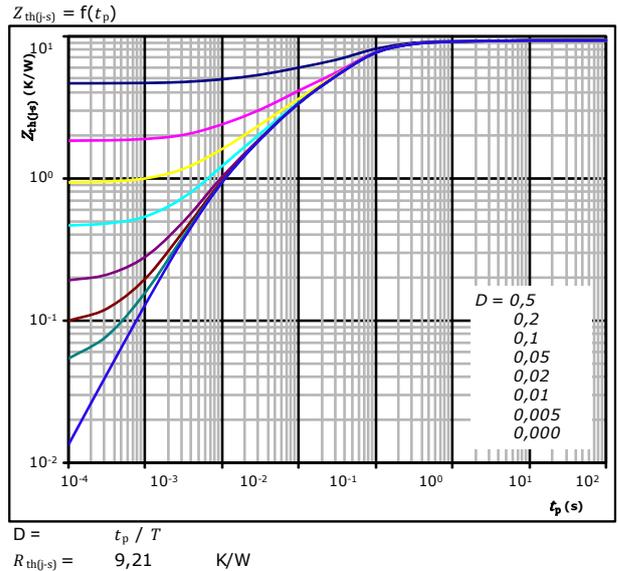


### Brake Sw. Protection Diode Characteristics

**figure 1.** FWD  
Typical forward characteristics



**figure 2.** FWD  
Transient thermal impedance as a function of pulse width



FWD thermal model values

| $R$ (K/W) | $\tau$ (s) |
|-----------|------------|
| 2,80E-01  | 2,78E+00   |
| 1,47E+00  | 1,77E-01   |
| 4,89E+00  | 4,55E-02   |
| 1,92E+00  | 5,08E-03   |
| 6,42E-01  | 7,39E-04   |

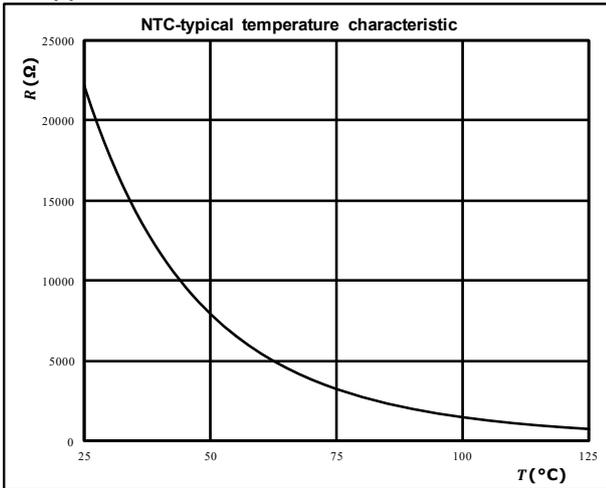


## Thermistor Characteristics

figure 1. Thermistor

Typical NTC characteristic  
as a function of temperature

$$R = f(T)$$

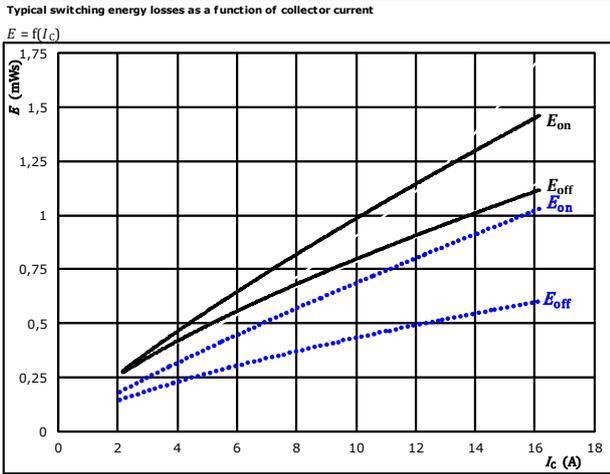




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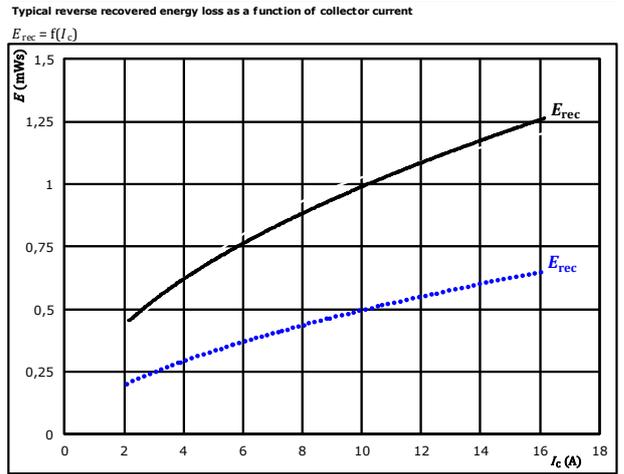
## Inverter Switching Characteristics

**figure 1.** IGBT



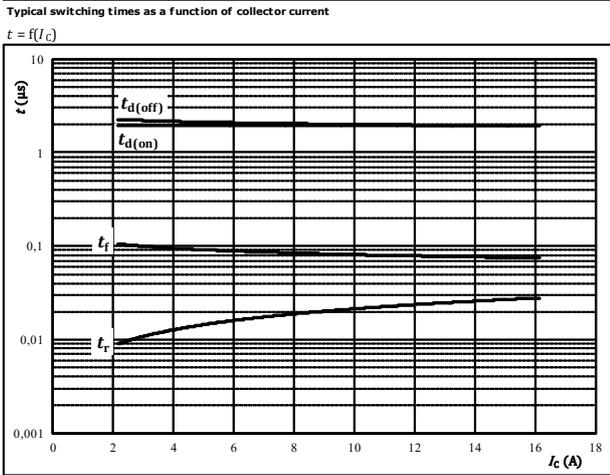
With an inductive load at  
 $V_{CE} = 600$  V  
 $V_{CC} = 15$  V  
 $V_{IN} = 5$  V  
 $T_j = 125$  °C

**figure 2.** FWD



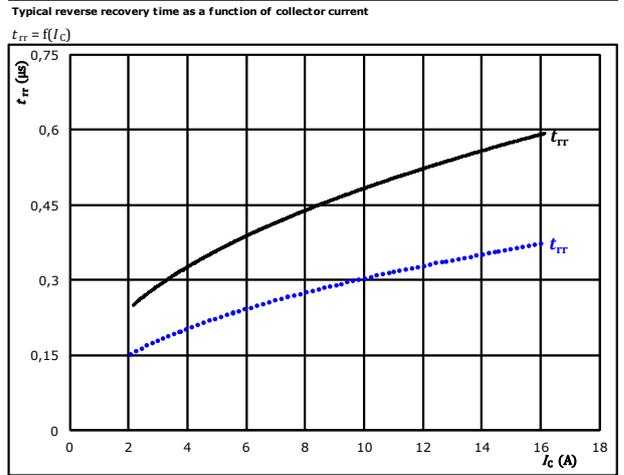
With an inductive load at  
 $V_{CE} = 600$  V  
 $V_{CC} = 15$  V  
 $V_{IN} = 5$  V  
 $T_j = 125$  °C

**figure 3.** IGBT



With an inductive load at  
 $T_j = 125$  °C  
 $V_{CE} = 600$  V  
 $V_{CC} = 15$  V  
 $V_{IN} = 5$  V

**figure 4.** FWD

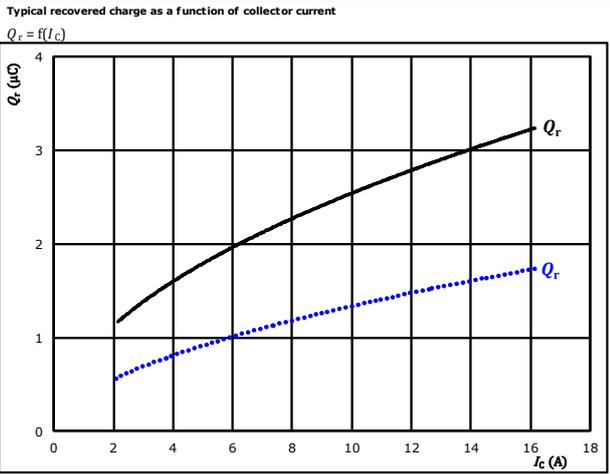


At  
 $V_{CE} = 600$  V  
 $V_{CC} = 15$  V  
 $V_{IN} = 5$  V  
 $T_j = 125$  °C



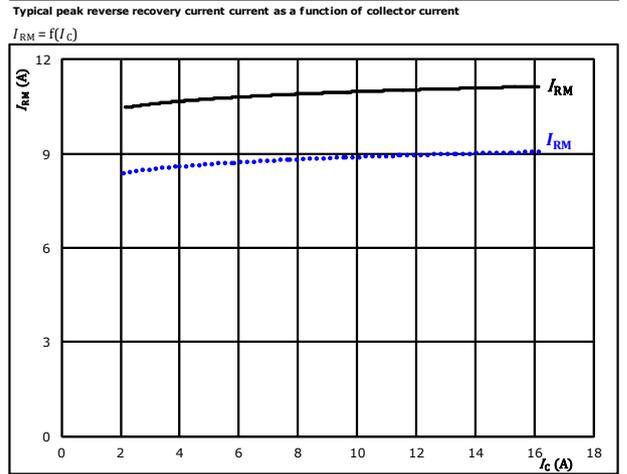
## Inverter Switching Characteristics

figure 5. FWD



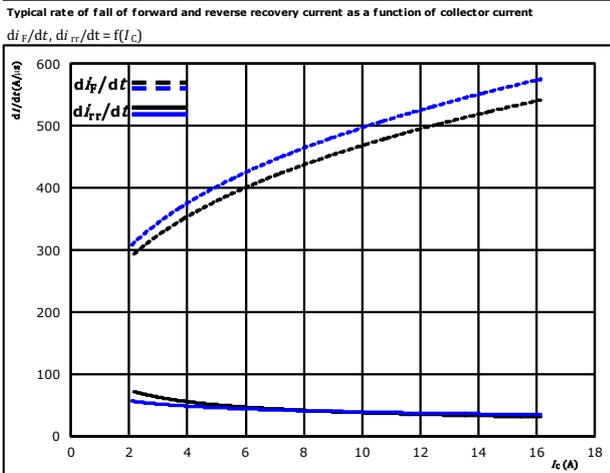
At  $V_{CE} = 600$  V  $T_j = 25$  °C (dotted blue line)  
 $V_{CC} = 15$  V  $T_j = 125$  °C (solid black line)  
 $V_{IN} = 5$  V

figure 6. FWD



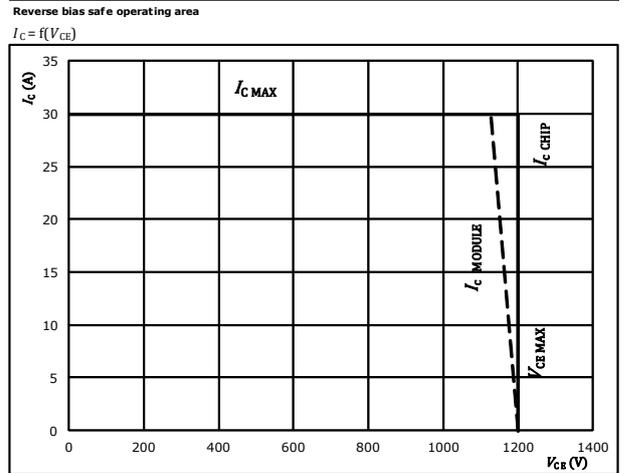
At  $V_{CE} = 600$  V  $T_j = 25$  °C (dotted blue line)  
 $V_{CC} = 15$  V  $T_j = 125$  °C (solid black line)  
 $V_{IN} = 5$  V

figure 7. FWD



At  $V_{CE} = 600$  V  $T_j = 25$  °C (dotted blue line)  
 $V_{CC} = 15$  V  $T_j = 125$  °C (solid black line)  
 $V_{IN} = 5$  V

figure 8. IGBT



At  $T_j = 175$  °C



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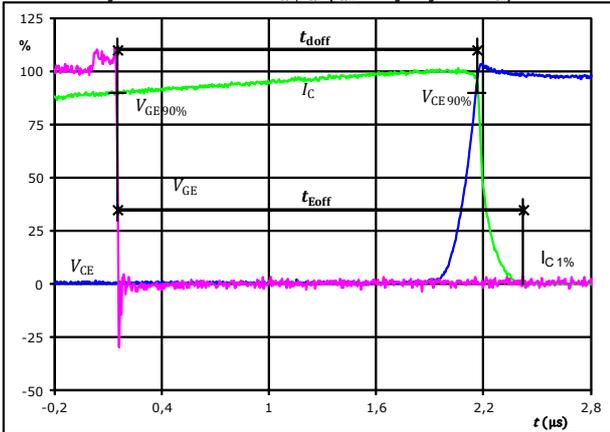
## Inverter Switching Definitions

**General conditions**

|            |   |              |
|------------|---|--------------|
| $T_j$      | = | 125 °C       |
| $R_{gon}$  | = | 0,5 $\Omega$ |
| $R_{goff}$ | = | 0,5 $\Omega$ |

**figure 1.** IGBT

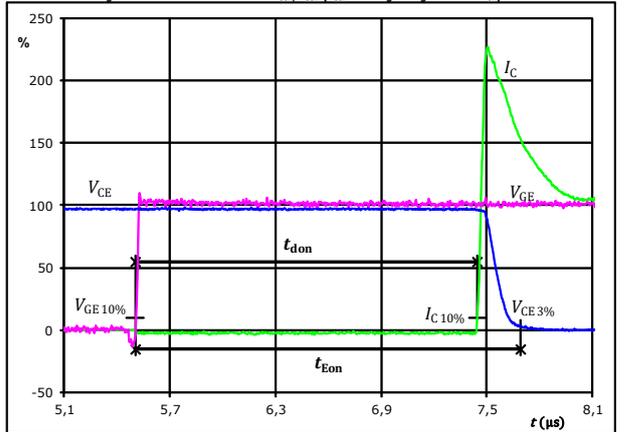
Turn-off Switching Waveforms & definition of  $t_{doff}$ ,  $t_{Eoff}$  ( $t_{Eoff}$  = integrating time for  $E_{off}$ )



|                   |       |         |
|-------------------|-------|---------|
| $V_{CE}(0\%) =$   | 0     | V       |
| $V_{GE}(100\%) =$ | 5     | V       |
| $V_C(100\%) =$    | 600   | V       |
| $I_C(100\%) =$    | 9     | A       |
| $t_{doff} =$      | 2,012 | $\mu s$ |
| $t_{Eoff} =$      | 2,271 | $\mu s$ |

**figure 2.** IGBT

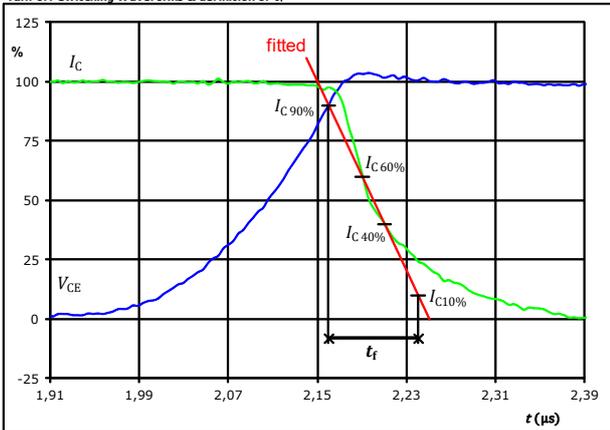
Turn-on Switching Waveforms & definition of  $t_{don}$ ,  $t_{Eon}$  ( $t_{Eon}$  = integrating time for  $E_{on}$ )



|                   |       |         |
|-------------------|-------|---------|
| $V_{CE}(0\%) =$   | 0     | V       |
| $V_{GE}(100\%) =$ | 5     | V       |
| $V_C(100\%) =$    | 600   | V       |
| $I_C(100\%) =$    | 9     | A       |
| $t_{don} =$       | 1,938 | $\mu s$ |
| $t_{Eon} =$       | 2,187 | $\mu s$ |

**figure 3.** IGBT

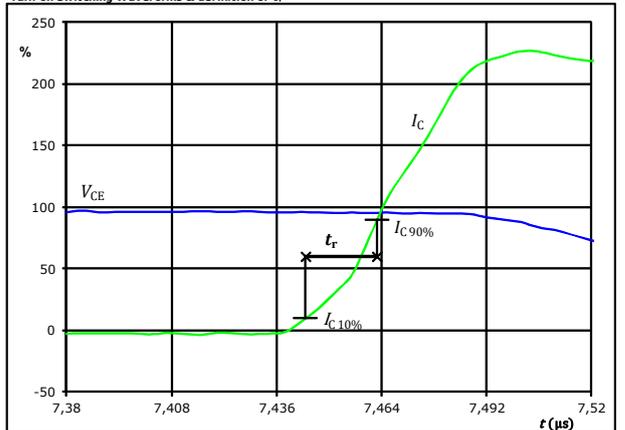
Turn-off Switching Waveforms & definition of  $t_f$



|                |       |         |
|----------------|-------|---------|
| $V_C(100\%) =$ | 600   | V       |
| $I_C(100\%) =$ | 9     | A       |
| $t_f =$        | 0,088 | $\mu s$ |

**figure 4.** IGBT

Turn-on Switching Waveforms & definition of  $t_r$



|                |       |         |
|----------------|-------|---------|
| $V_C(100\%) =$ | 600   | V       |
| $I_C(100\%) =$ | 9     | A       |
| $t_r =$        | 0,019 | $\mu s$ |

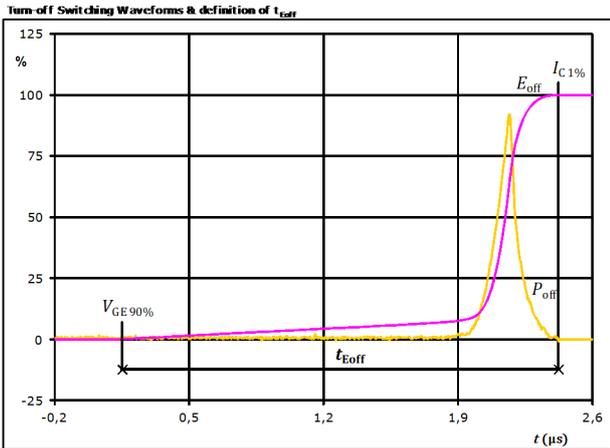
\*  $t_{don}$ ,  $t_{doff}$  include gate driver propagation delay



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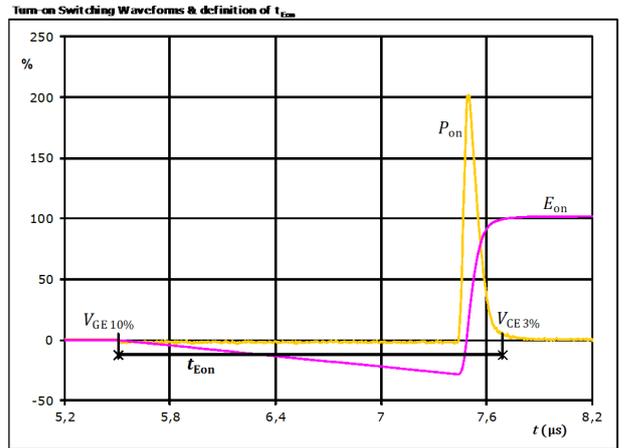
## Inverter Switching Characteristics

figure 5. IGBT



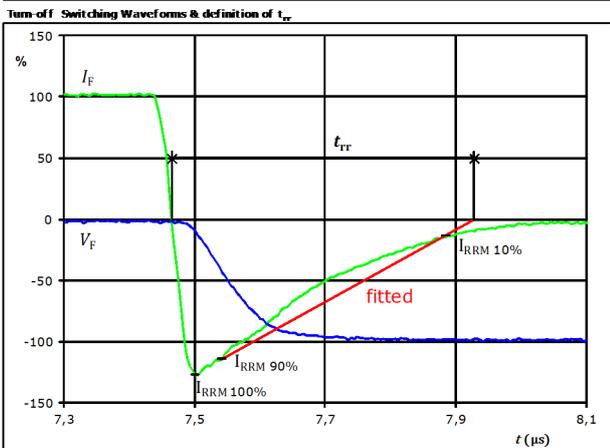
$P_{off}(100\%) = 5,43$  kW  
 $E_{off}(100\%) = 0,73$  mJ  
 $t_{Eoff} = 2,27$   $\mu s$

figure 6. IGBT



$P_{on}(100\%) = 5,43$  kW  
 $E_{on}(100\%) = 0,82$  mJ  
 $t_{Eon} = 2,19$   $\mu s$

figure 7. FWD

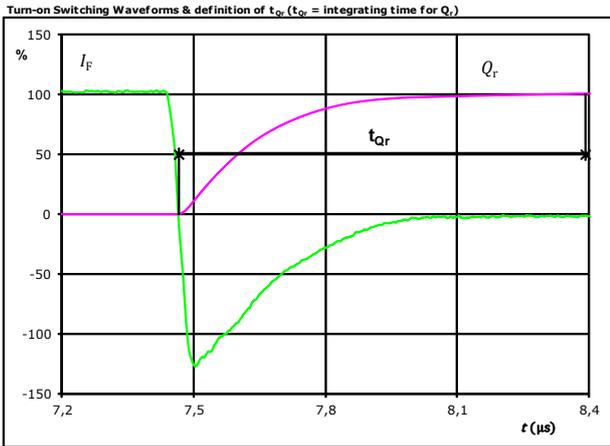


$V_F(100\%) = 600$  V  
 $I_F(100\%) = 9$  A  
 $I_{RRM}(100\%) = -12$  A  
 $t_{rr} = 0,463$   $\mu s$



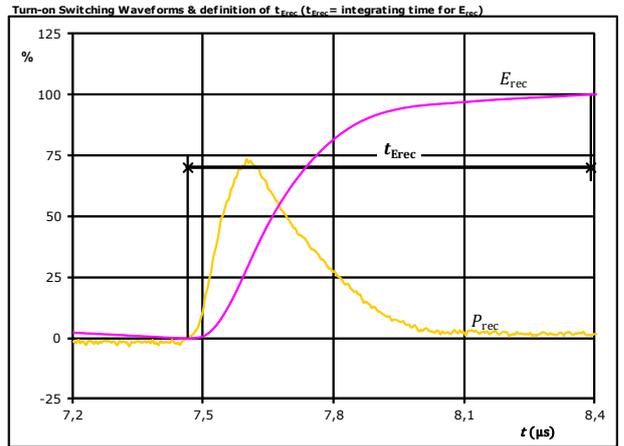
### Inverter Switching Characteristics

figure 8. FWD



|                |      |               |
|----------------|------|---------------|
| $I_F$ (100%) = | 9    | A             |
| $Q_r$ (100%) = | 2,49 | $\mu\text{C}$ |
| $t_{Qr}$ =     | 0,93 | $\mu\text{s}$ |

figure 9. FWD

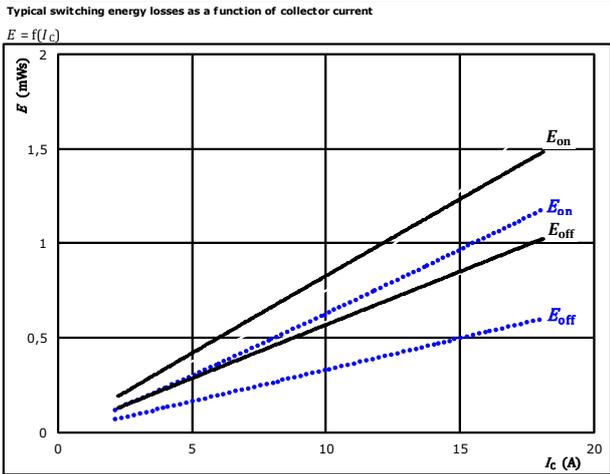


|                    |      |               |
|--------------------|------|---------------|
| $P_{rec}$ (100%) = | 5,43 | kW            |
| $E_{rec}$ (100%) = | 0,99 | mJ            |
| $t_{Erec}$ =       | 0,93 | $\mu\text{s}$ |



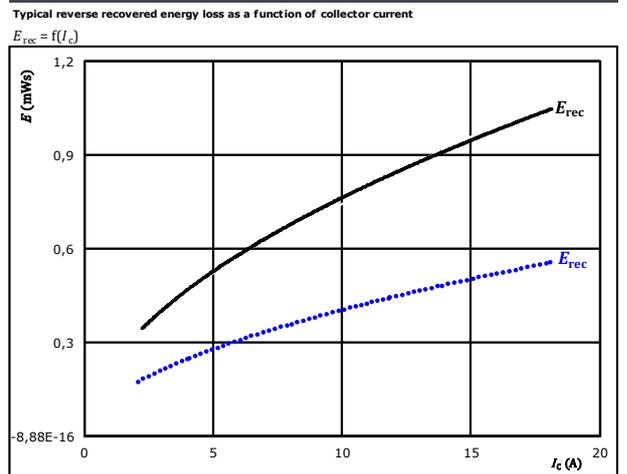
### Brake Switching Characteristics

**figure 1.** IGBT



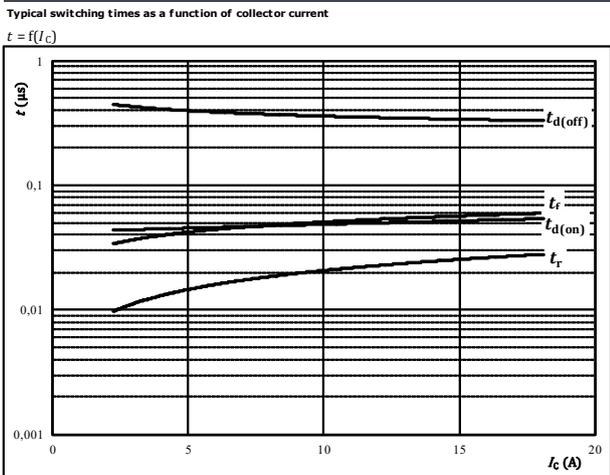
With an inductive load at  
 $V_{CE} = 600$  V  
 $V_{IN} = 5$  V  
 $V_{CC} = 15,0$  V  
 $T_j = 125$  °C

**figure 2.** FWD



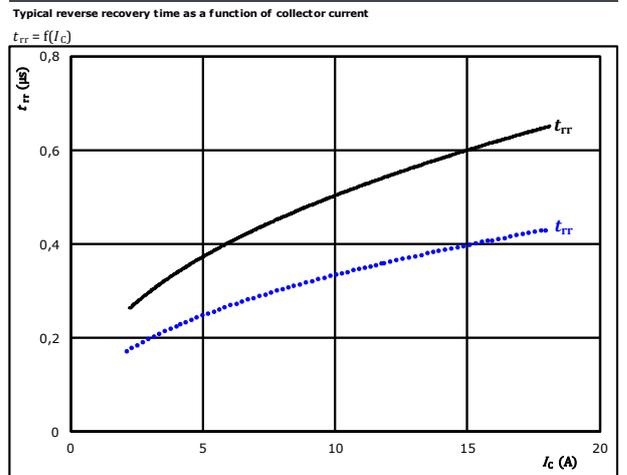
With an inductive load at  
 $V_{CE} = 600$  V  
 $V_{IN} = 5$  V  
 $V_{CC} = 15,0$  V  
 $T_j = 125$  °C

**figure 3.** IGBT



With an inductive load at  
 $T_j = 125$  °C  
 $V_{CE} = 600$  V  
 $V_{IN} = 5$  V  
 $V_{CC} = 15,0$  V

**figure 4.** FWD



At  
 $V_{CE} = 600$  V  
 $V_{IN} = 5$  V  
 $V_{CC} = 15,0$  V  
 $T_j = 125$  °C

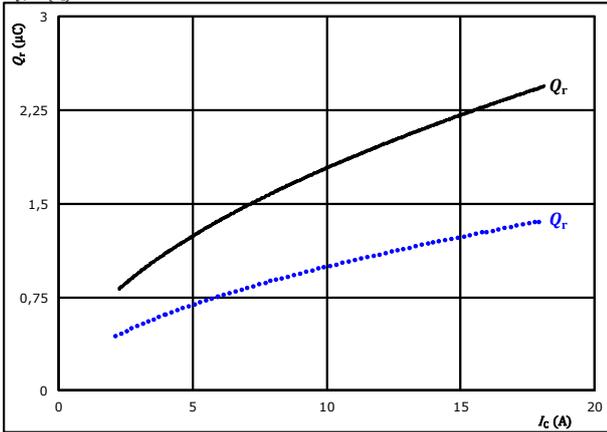


## Brake Switching Characteristics

figure 5. FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$

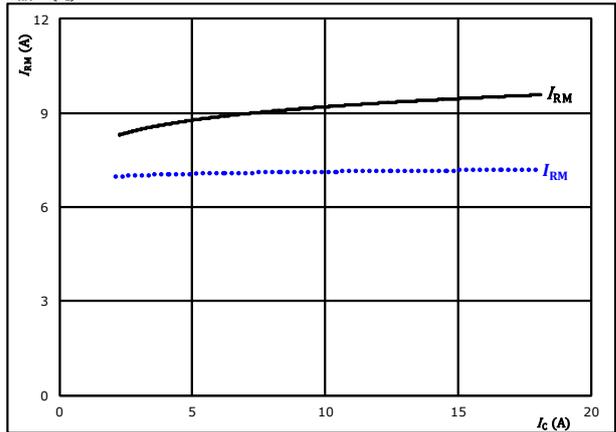


At  $V_{CE} = 600$  V  $T_j = 25$  °C (dotted blue line)  
 $V_{IN} = 5$  V  $T_j = 125$  °C (solid black line)  
 $V_{CC} = 15,0$  V

figure 6. FWD

Typical peak reverse recovery current current as a function of collector current

$$I_{RM} = f(I_c)$$

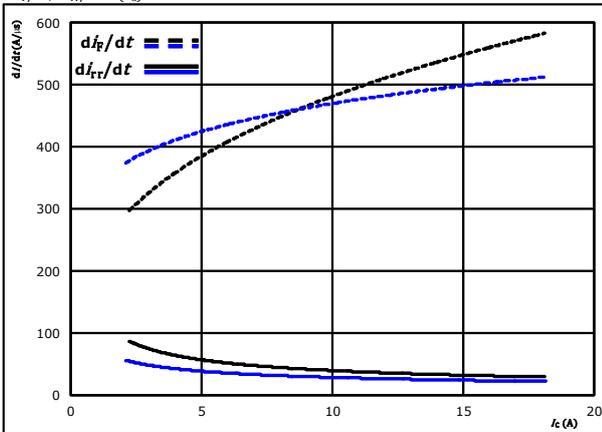


At  $V_{CE} = 600$  V  $T_j = 25$  °C (dotted blue line)  
 $V_{IN} = 5$  V  $T_j = 125$  °C (solid black line)  
 $V_{CC} = 15,0$  V

figure 7. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current

$$di_f/dt, di_{rr}/dt = f(I_c)$$

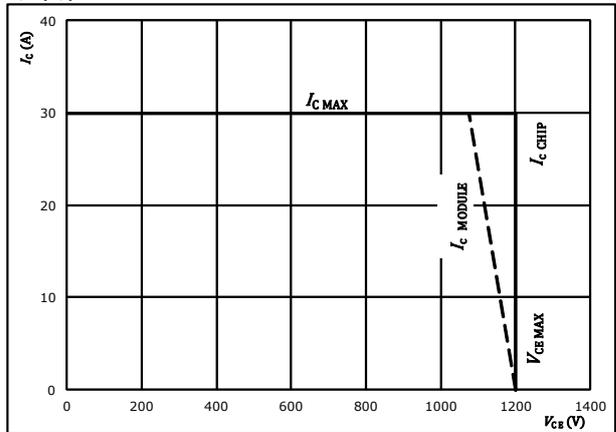


At  $V_{CE} = 600$  V  $T_j = 25$  °C (dotted blue line)  
 $V_{IN} = 5$  V  $T_j = 125$  °C (solid black line)  
 $V_{CC} = 15,0$  V

figure 8. IGBT

Reverse bias safe operating area

$$I_c = f(V_{CE})$$



At  $T_j = 175$  °C



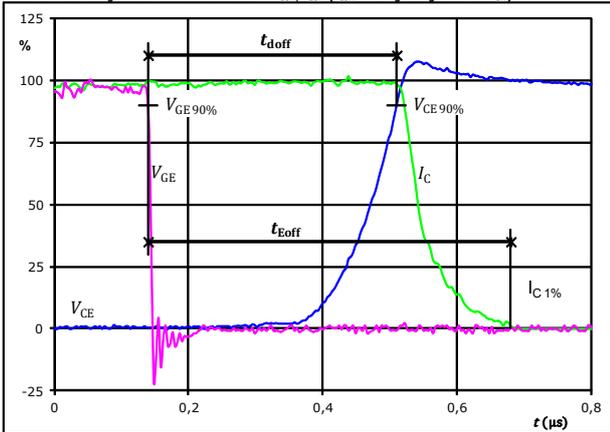
## Brake Switching Definitions

**General conditions**

|          |   |        |
|----------|---|--------|
| $T_j$    | = | 125 °C |
| $V_{CC}$ | = | 15 V   |

**figure 1.** IGBT

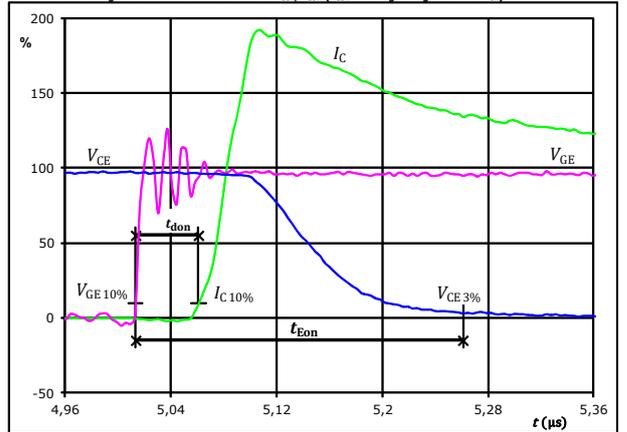
Turn-off Switching Waveforms & definition of  $t_{doff}$ ,  $t_{Eoff}$  ( $t_{Eoff}$  = integrating time for  $E_{off}$ )



|                   |       |         |
|-------------------|-------|---------|
| $V_{IN}(0\%) =$   | 0     | V       |
| $V_{IN}(100\%) =$ | 5     | V       |
| $V_C(100\%) =$    | 600   | V       |
| $I_C(100\%) =$    | 10    | A       |
| $t_{doff} =$      | 0,369 | $\mu s$ |
| $t_{Eoff} =$      | 0,541 | $\mu s$ |

**figure 2.** IGBT

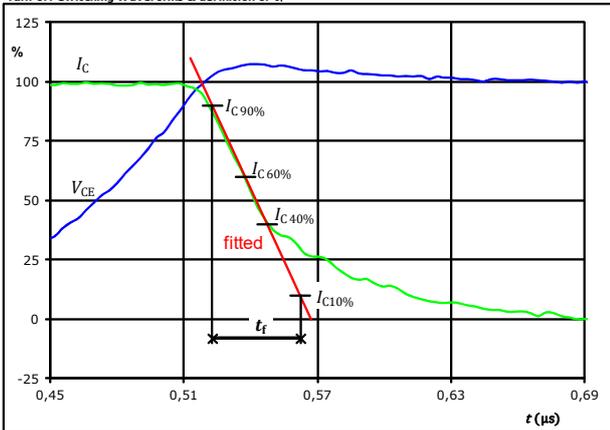
Turn-on Switching Waveforms & definition of  $t_{don}$ ,  $t_{Eon}$  ( $t_{Eon}$  = integrating time for  $E_{on}$ )



|                   |       |         |
|-------------------|-------|---------|
| $V_{IN}(0\%) =$   | 0     | V       |
| $V_{IN}(100\%) =$ | 5     | V       |
| $V_C(100\%) =$    | 600   | V       |
| $I_C(100\%) =$    | 10    | A       |
| $t_{don} =$       | 0,049 | $\mu s$ |
| $t_{Eon} =$       | 0,248 | $\mu s$ |

**figure 3.** IGBT

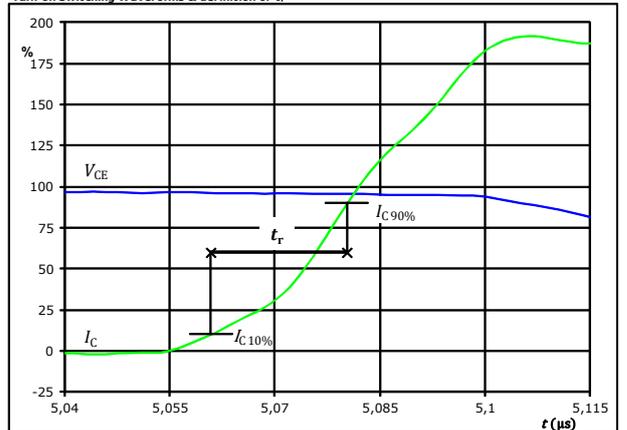
Turn-off Switching Waveforms & definition of  $t_f$



|                |       |         |
|----------------|-------|---------|
| $V_C(100\%) =$ | 600   | V       |
| $I_C(100\%) =$ | 10    | A       |
| $t_f =$        | 0,043 | $\mu s$ |

**figure 4.** IGBT

Turn-on Switching Waveforms & definition of  $t_r$



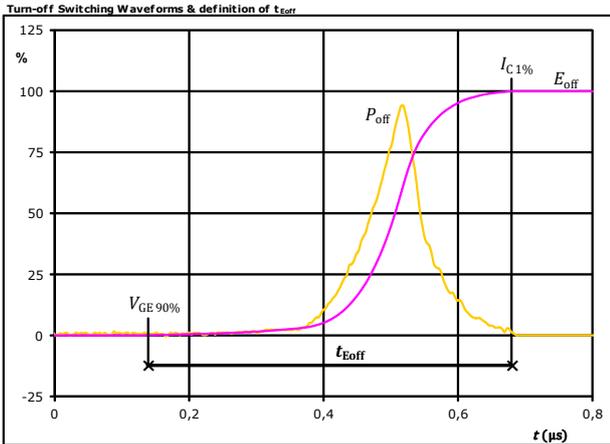
|                |       |         |
|----------------|-------|---------|
| $V_C(100\%) =$ | 600   | V       |
| $I_C(100\%) =$ | 10    | A       |
| $t_r =$        | 0,020 | $\mu s$ |



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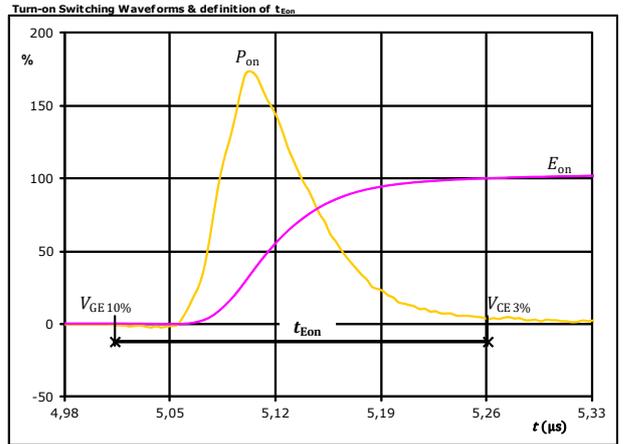
### Brake Switching Characteristics

figure 5. IGBT



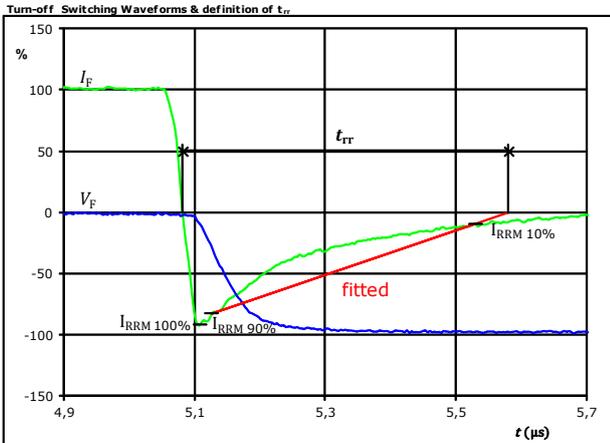
|                    |      |    |
|--------------------|------|----|
| $P_{off}(100\%) =$ | 6,15 | kW |
| $E_{off}(100\%) =$ | 0,60 | mJ |
| $t_{Eoff} =$       | 0,54 | μs |

figure 6. IGBT



|                   |      |    |
|-------------------|------|----|
| $P_{on}(100\%) =$ | 6,15 | kW |
| $E_{on}(100\%) =$ | 0,77 | mJ |
| $t_{Eon} =$       | 0,25 | μs |

figure 7. FWD



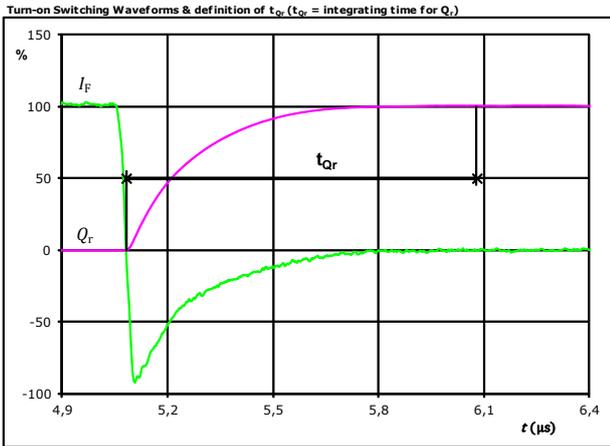
|                    |       |    |
|--------------------|-------|----|
| $V_F(100\%) =$     | 600   | V  |
| $I_F(100\%) =$     | 10    | A  |
| $I_{RRM}(100\%) =$ | -9    | A  |
| $t_{rr} =$         | 0,494 | μs |



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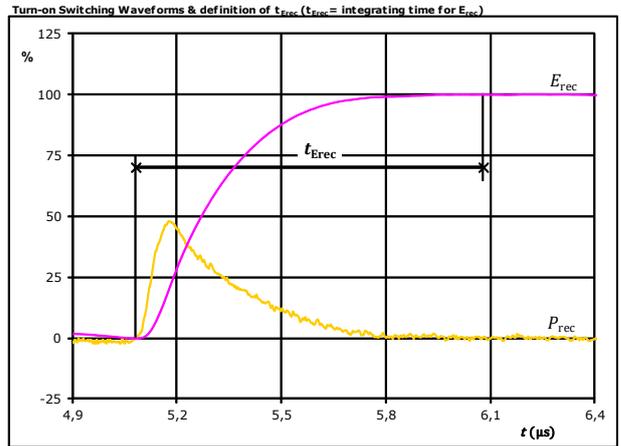
### Brake Switching Characteristics

figure 8. FWD



|                |      |               |
|----------------|------|---------------|
| $I_F$ (100%) = | 10   | A             |
| $Q_r$ (100%) = | 1,76 | $\mu\text{C}$ |
| $t_{Qr}$ =     | 1,00 | $\mu\text{s}$ |

figure 9. FWD



|                    |      |               |
|--------------------|------|---------------|
| $P_{rec}$ (100%) = | 6,15 | kW            |
| $E_{rec}$ (100%) = | 0,75 | mJ            |
| $t_{Erec}$ =       | 1,00 | $\mu\text{s}$ |



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| Ordering Code & Marking  |                           |            |                             |           |       |        |      |      |  |           |          |     |        |                           |  |      |        |       |      |            |          |            |        |           |  |  |         |       |      |      |  |  |
|--|---------------------------|------------|-----------------------------|-----------|-------|--------|------|------|--|-----------|----------|-----|--------|---------------------------|--|------|--------|-------|------|------------|----------|------------|--------|-----------|--|--|---------|-------|------|------|--|--|
| <b>Version</b>   |                           |            | <b>Ordering Code</b>        |           |       |        |      |      |  |           |          |     |        |                           |  |      |        |       |      |            |          |            |        |           |  |  |         |       |      |      |  |  |
| without thermal paste 12 mm housing with solder pins   |                           |            | 20-1C12IBA015SH-LB18A08     |           |       |        |      |      |  |           |          |     |        |                           |  |      |        |       |      |            |          |            |        |           |  |  |         |       |      |      |  |  |
| with thermal paste 12 mm housing with solder pins  |                           |            | 20-1C12IBA015SH-LB18A08-/3/ |           |       |        |      |      |  |           |          |     |        |                           |  |      |        |       |      |            |          |            |        |           |  |  |         |       |      |      |  |  |
| <table border="1"> <thead> <tr> <th rowspan="2">Text</th> <th colspan="2">Name</th> <th>Date code</th> <th>UL &amp; VIN</th> <th>Lot</th> <th>Serial</th> </tr> <tr> <td colspan="2">NN-NNNNNNNNNNNNNN-TTTTTWW</td> <td>WWYY</td> <td>UL VIN</td> <td>LLLLL</td> <td>SSSS</td> </tr> </thead> <tbody> <tr> <td rowspan="2">Datamatrix</td> <td>Type&amp;Ver</td> <td>Lot number</td> <td>Serial</td> <td>Date code</td> <td></td> <td></td> </tr> <tr> <td>TTTTTWW</td> <td>LLLLL</td> <td>SSSS</td> <td>WWYY</td> <td></td> <td></td> </tr> </tbody> </table> |                           |            |                             |           |       |        | Text | Name |  | Date code | UL & VIN | Lot | Serial | NN-NNNNNNNNNNNNNN-TTTTTWW |  | WWYY | UL VIN | LLLLL | SSSS | Datamatrix | Type&Ver | Lot number | Serial | Date code |  |  | TTTTTWW | LLLLL | SSSS | WWYY |  |  |
| Text   | Name                      |            | Date code                   | UL & VIN  | Lot   | Serial |      |      |  |           |          |     |        |                           |  |      |        |       |      |            |          |            |        |           |  |  |         |       |      |      |  |  |
|  | NN-NNNNNNNNNNNNNN-TTTTTWW |            | WWYY                        | UL VIN    | LLLLL | SSSS   |      |      |  |           |          |     |        |                           |  |      |        |       |      |            |          |            |        |           |  |  |         |       |      |      |  |  |
| Datamatrix   | Type&Ver                  | Lot number | Serial                      | Date code |       |        |      |      |  |           |          |     |        |                           |  |      |        |       |      |            |          |            |        |           |  |  |         |       |      |      |  |  |
|  | TTTTTWW                   | LLLLL      | SSSS                        | WWYY      |       |        |      |      |  |           |          |     |        |                           |  |      |        |       |      |            |          |            |        |           |  |  |         |       |      |      |  |  |

| Pin table |       |       |          |
|-----------|-------|-------|----------|
| Pin       | X     | Y     | Function |
| 1         | 45,1  | 0     | WH       |
| 2         | 42,4  | 0     | WL       |
| 3         | 39,7  | 0     | RW+      |
| 4         | 37    | 0     | RW-      |
| 5         | 34,3  | 0     | GND      |
| 6         | 31,6  | 0     | VCC      |
| 7         | 28,9  | 0     | VH       |
| 8         | 26,2  | 0     | VL       |
| 9         | 23,5  | 0     | RV+      |
| 10        | 20,8  | 0     | RV-      |
| 11        | 18,1  | 0     | UH       |
| 12        | 15,4  | 0     | UL       |
| 13        | 12,7  | 0     | RU+      |
| 14        | 10    | 0     | RU-      |
| 15        | 7,3   | 0     | RST      |
| 16        | 4,6   | 0     | FO       |
| 17        | 1,9   | 0     | NTC      |
| 18        | 0     | 2,6   | BRCG     |
| 19        | 0     | 11,5  | L3       |
| 20        | 0,55  | 20,4  | L2       |
| 21        | 0     | 29,55 | L1       |
| 22        | 8,15  | 20,9  | DC1-     |
| 23        | 8,4   | 33,03 | BRE      |
| 24        | 12,4  | 26,45 | EU       |
| 25        | 24,1  | 26,45 | EV       |
| 26        | 37,1  | 26,65 | EW       |
| 27        | 45,1  | 35,05 | DC2+     |
| 28        | 32,85 | 35,05 | DC2+     |
| 29        | 20,35 | 35,05 | DC2+     |
| 30        | 0     | 38,55 | DC1+     |
| 31        | 0     | 42,1  | BRC+     |
| 32        | 8,4   | 42,1  | BRC      |
| 33        | 16,7  | 42,1  | U        |
| 34        | 29,2  | 42,1  | V        |
| 35        | 41,35 | 42,1  | W        |

Tolerance of pinpositions: ±0.5mm at the end of pins  
Dimension of coordinate axis is only offset without tolerance

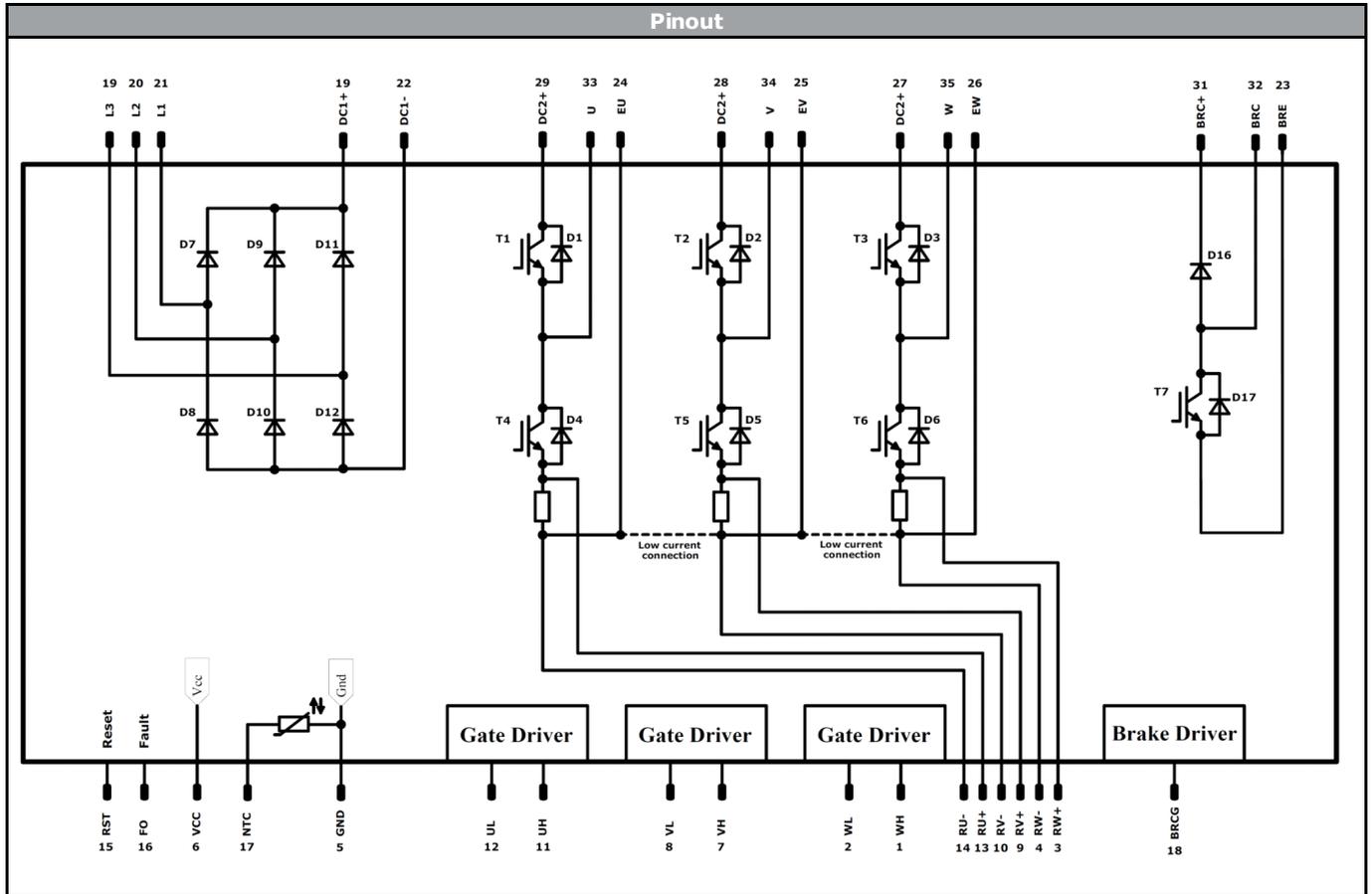


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| Pin Descriptions |          |   |                        |          |                      |
|------------------|----------|---|------------------------|----------|----------------------|
| Pin              | Function | Description   | Power pin descriptions |          |                      |
|                  |          |   | Pin                    | Function | Description          |
| 1                | WH       | Signal input for high-side W phase                    | 19                     | L3       | Rectifier input L3   |
| 2                | WL       | Signal input for low-side W phase                     | 20                     | L2       | Rectifier input L2   |
| 3                | RW+      | W phase shunt +                                       | 21                     | L1       | Rectifier input L1   |
| 4                | RW-      | W phase shunt -                                       | 22                     | DC1-     | Rectifier output DC- |
| 5                | GND      | Signal ground   | 23                     | BRE      | Brake Open emitter   |
| 6                | VCC      | Driver circuit supply voltage                         | 24                     | EU       | Open emitter U phase |
| 7                | VH       | Signal input for high-side V phase                    | 25                     | EV       | Open emitter V phase |
| 8                | VL       | Signal input for low-side V phase                     | 26                     | EW       | Open emitter W phase |
| 9                | RV+      | V phase shunt +                                       | 27                     | DC2+     | Inverter input DC+   |
| 10               | RV-      | V phase shunt -                                       | 28                     | DC2+     | Inverter input DC+   |
| 11               | UH       | Signal input for high-side U phase                    | 29                     | DC2+     | Inverter input DC+   |
| 12               | UL       | Signal input for low-side U phase                     | 30                     | DC1+     | Rectifier output DC+ |
| 13               | RU+      | U phase shunt +                                       | 31                     | BRC+     | Brake input DC+      |
| 14               | RU-      | U phase shunt -                                       | 32                     | BRC      | Brake output         |
| 15               | RST      | Fault latch reset (min. 500ns pulse)                  | 33                     | U        | Output U phase       |
| 16               | FO       | Fault latch input/output (negative logic, open drain) | 34                     | V        | Output V phase       |
| 17               | NTC      | Temperature sensor connector                          | 35                     | W        | Output W phase       |
| 18               | BRCG     | Signal input for Brake gate drive                     |                        |          |                      |



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| Identification            |           |         |         |                            |         |
|---------------------------|-----------|---------|---------|----------------------------|---------|
| ID                        | Component | Voltage | Current | Function                   | Comment |
| D8, D7, D10, D9, D12, D11 | Rectifier | 1600 V  | 30 A    | Rectifier Diode            |         |
| T4, T1, T5, T2, T6, T3    | IGBT      | 1200 V  | 15 A    | Inverter Switch            |         |
| D1, D4, D2, D5, D3, D6    | FWD       | 1200 V  | 15 A    | Inverter Diode             |         |
| R1, R2, R3                | Resistor  |         | 9 A     | Inverter Shunt             |         |
| T7                        | IGBT      | 1200 V  | 15 A    | Brake Switch               |         |
| D16                       | FWD       | 1200 V  | 7,5 A   | Brake Diode                |         |
| D17                       | FWD       | 1200 V  | 3 A     | Brake Sw. Protection Diode |         |



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| Packaging instruction                |      |          |             |
|--------------------------------------|------|----------|-------------|
| Standard packaging quantity (SPQ) 90 | >SPQ | Standard | <SPQ Sample |

| Handling instruction   |
|--|
| Handling instructions for <i>flow</i> 1C packages see vincotech.com website. |

| Package data  |
|---|
| Package data for <i>flow</i> 1C packages see vincotech.com website. |

| UL recognition and file number  |
|---|
| This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.  |

| Document No.:                 | Date:        | Modification:                         | Pages |
|-------------------------------|--------------|---------------------------------------|-------|
| 20-1C12IBA015SH-LB18A08-D3-14 | 07 Feb. 2020 | Correct $V_{CC}$ of Gate Driver Brake | 3, 9  |

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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